



INTERNATIONAL ATOMIC ENERGY AGENCY
UNITED NATIONS EDUCATIONAL, SCIENTIFIC AND CULTURAL ORGANIZATION



INTERNATIONAL CENTRE FOR THEORETICAL PHYSICS
34100 TRIESTE (ITALY) - P.O. B. 586 - MIRAMARE - STRADA COSTIERA 11 - TELEPHONE: 2240-1
CABLE: CENTRATOM - TELEX 460392-1

SMR/384 - 12

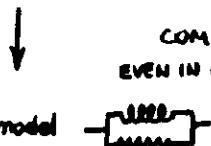
EXPERIMENTAL WORKSHOP ON
"HIGH TEMPERATURE SUPERCONDUCTORS"
(30 March - 14 April 1989)

MAGNETIC AND TRANSPORT PROPERTIES

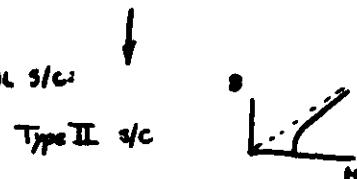
R.B. VAN DOVER
AT&T Bell Laboratories
600 Mountain Avenue
Murray Hill, NJ 07974-2070
U.S.A.

TWO KEY PROPERTIES

$R = 0$ zero resistance



$B = 0$ Meissner effect



COMPLICATIONS
EVEN IN CONVENTIONAL S/C:

two fluid model

Type II s/c

UNCONVENTIONAL BEHAVIOR

anisotropy in m^*

IN HTSC:

anisotropy in H_{c1}, H_{c2} , etc

flux creep, flux flow

flux lattice melting

fluctuations

spin glass -

percolation, weak links
especially in ceramics,
films

THE ISSUE IS, DO THESE UNCONVENTIONAL
BEHAVIORS REFLECT NEW PHYSICS?

ORGANIZATION

1. magnetostatics

demagnetization, H_{c1} , Meissner effect, flux melting

2. dc transport zero field

normal-state $\rho(T)$, ceramics, screening

3. resistive transition in a field

flux motion, dissipation, phase boundary

4. critical currents

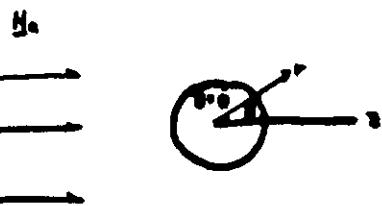
transport: depinning, weak links, thin films

magnetization: critical state, bean model, magnetization decay

MAGNETOSTATICS

demagnetization

superconducting sphere in a uniform applied field



$$H_a = H_a \cos \theta \hat{r} + H_a \sin \theta \hat{\theta}$$

Meissner state $H = H_{ci}$

outside SC $J=0, M=0$

$$\nabla \cdot \mathbf{B} = 0$$

$$\mathbf{g} \times \mathbf{B} = 0$$

$$\nabla^2 V_m = 0 \quad \begin{matrix} \text{magnetic} \\ \text{scalar} \\ \text{potential} \end{matrix}$$

$$\nabla^2 V_m = 0$$

boundary condition

$$B_r = 0 \text{ at } r = a$$

outside skin:

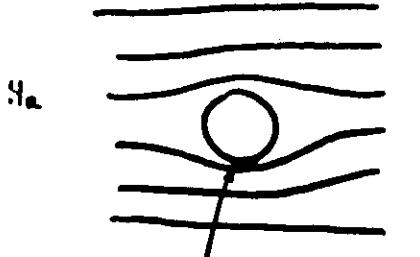
$$B_\theta = \left(H_a - H_a \frac{a^2}{r^2} \right) \cos \theta$$

$$B_\theta = -\left(H_a + H_a \frac{a^2}{2r^2} \right) \sin \theta$$

max B at $\theta = \pm \frac{\pi}{2}$

$$\frac{3}{2} H_a$$

$$\therefore B_\theta(r, \theta) = \frac{3}{2} H_a$$



max B at $\theta = \pm \frac{\pi}{2}$

$$\frac{3}{2} H_a$$

inside $r < a$

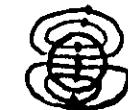
$$\mathbf{B} = 0$$

boundary condition H_θ continuous (because $J_{real} = 0$)

$$\underline{H} = \underline{B} \text{ outside}$$

$$H_{ci} = B_{ci} = -\left(H_a + \frac{H_a a^2}{2r^2} \right) \sin \theta$$

$\Rightarrow H_{ci}$ is uniform



$$H_{ci} = \frac{2}{3} H_a \quad \text{and} \quad M = -\frac{1}{3} H_a$$

e.g. $H_{ci} > H_{ci}$ for $H_a > \frac{2}{3} H_{ci}$

other geometries (demag factor well defined only for ellipsoids)

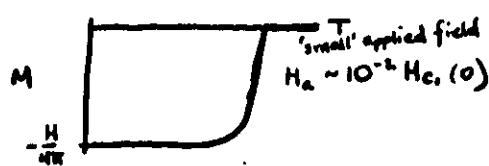
$$H_{ci} = H_a / l - n$$

cylinder, $H \parallel$ long axis	$n = 0$
cylinder $H \perp$ long axis	$n = \gamma_2$
sphere	γ_3
flat plate $H \perp \hat{n}$	0
flat plate $H \parallel \hat{n}$	$1 - 0\left(\frac{1}{a}\right)$

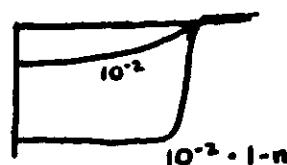


e.g. Chikazumi, Physics of Magnetism (Krieger) p19 ff.

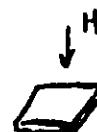
demagnetization M(T) curves



demag $n = 0$



demag $n = 1$



can be very small, e.g., $1-n \approx 0.01m$
 $1-n \approx .0158$

for $H_{ext} = 10$ Oe, must apply $.015$ Oe
 furthermore n is not well defined for rectangular parallelepiped



$$H_{c1}(0) = 200$$
 Oe



$$1.2$$
 kOe

$$H \parallel z$$



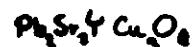
$$1.1$$
 kOe

$$\cdot$$



$$250$$

$$\text{atomic}$$



$$?$$

these values are very rough

use of 'meissner fraction' as a qualitative measure of superconducting volume fraction

empirical — not well-grounded theoretically

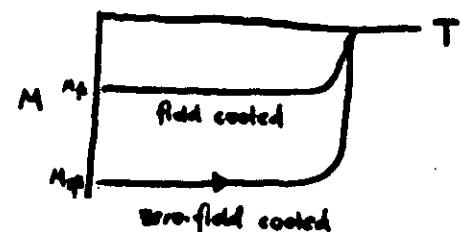
1. choose sample, ^{orient it} s.t. $n \sim 0$



2. cool in zero field

increase field to H_a ,
 measure $M(T)$

3. cool in H_a ,
 measure $M(T)$



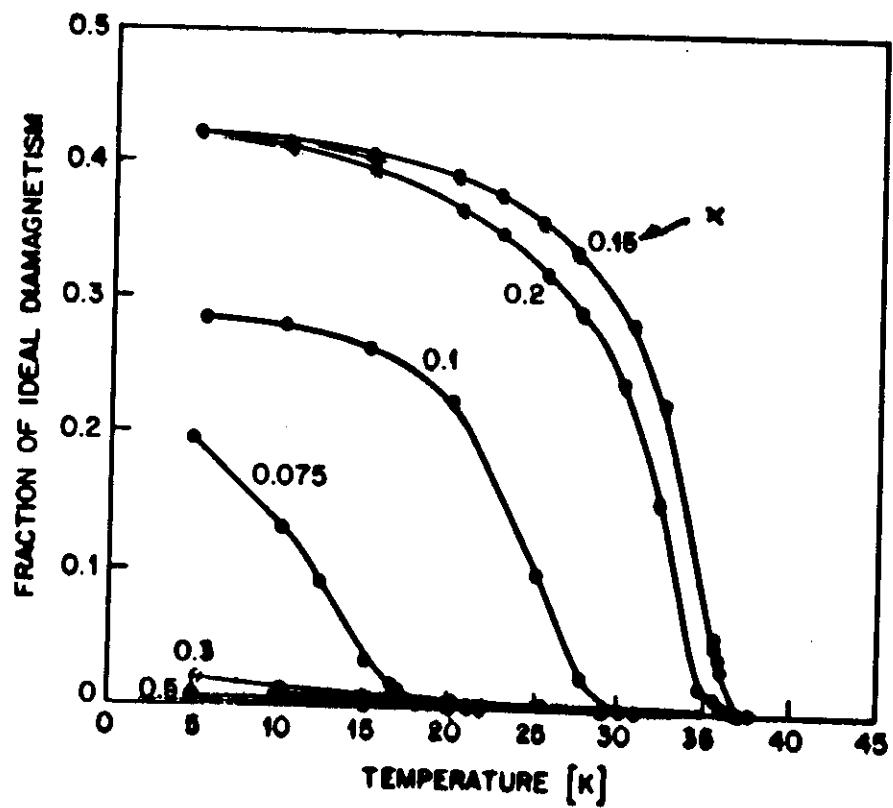
4. ratio $\frac{M_{fc}}{M_{zfc}}$

is indicative of sample quality

but not always: e.g. 99.999% Pb sphere, annealed

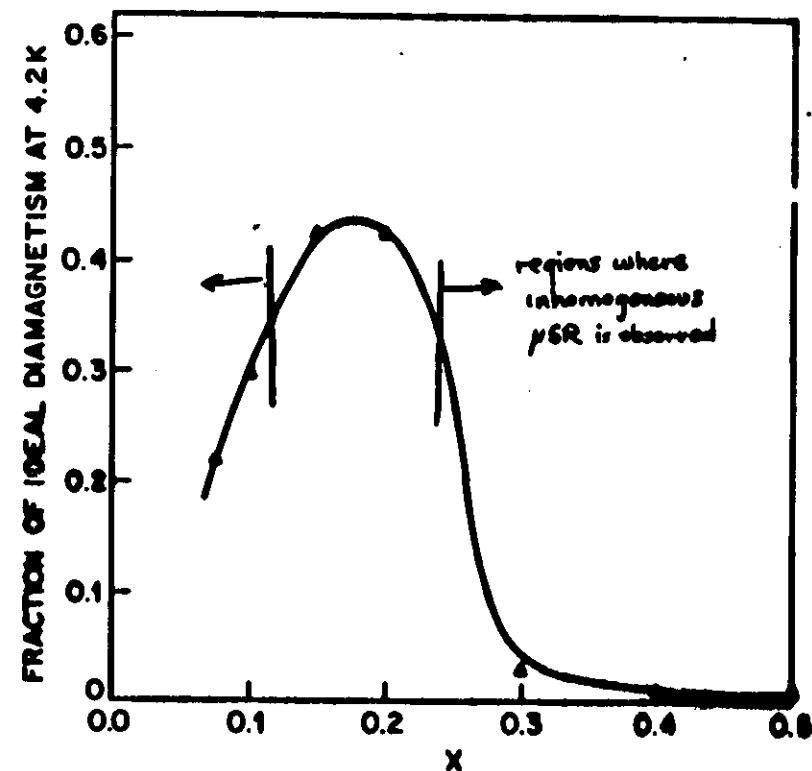
$$\frac{M_{fc}}{M_{zfc}} = 0.3 \quad \text{flux trapping}$$

$\text{La}_{2-x} \text{Sr}_x \text{CuO}_4$ (ceramic)



COMPOSITION DEPENDENCE

$\text{La}_{2-x} \text{Sr}_x \text{CuO}_4$



pSR muon spin rotation

- local probe
- inhomogeneity for $0.1 < x < 0.2$

quantitative measures of
superconducting volume fraction

heat capacity

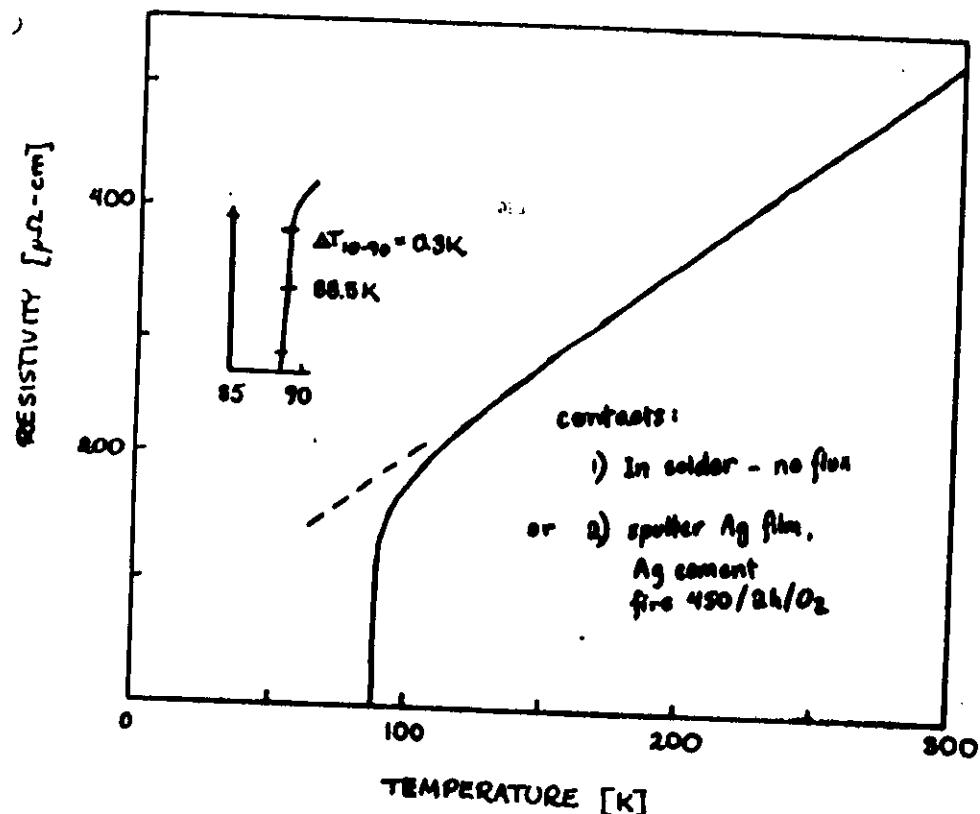
but need model to know what fractional ΔC_p jump
is expected

ultrasonic attenuation

RESISTIVITY OF UNDOPED $\text{Ba}_2\text{YCu}_3\text{O}_7$

- narrow transition
- linear in T

$\text{Ba}_2\text{YCu}_3\text{O}_7$ - crystal



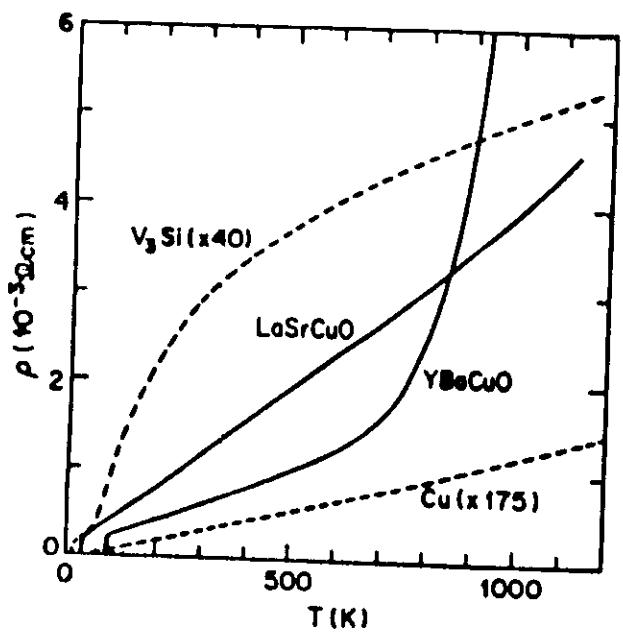
CONTACT RESISTIVITIES

Table 6. Formation of contacts to the surfaces of YBCO films and sintered pellets.

<u>Reference</u>	<u>Superconductor</u>	<u>Normal-Metal Contact</u>	<u>Processing Temperature</u>	<u>Measurement Temperature</u>	<u>ρ_c ($\Omega \cdot \text{cm}^2$)</u>
50-52	YBCO films or pellets	Ag paste, In solder, direct wire bonds, pressure contacts	20-100°C	77K	$10^{-2.10}$
Iye et al.(53)	YBCO single crystal	spark-bonded Au wire	800°C	100K	10^{-4}
Kusaka et al.(50)	YBCO pellet	evaporated Pt film	-100°C	80K	3×10^{-4}
Caton et al.(51)	YBCO pellet	evaporated Au film	500°C	80K	2×10^{-5}
Wieck(54)	YBCO pellet	sputtered Au film	20°C	77K	2×10^{-3}
van der Maas(55)	YBCO pellet	<u>melted Au bead</u>	1065°C	77K	5×10^{-7} ←
Sugimoto et al.(56)	ErBa ₂ Cu ₃ O ₇ pellet	pressed and sintered Au bead	950°C	<20K	4×10^{-7} ←
Tzeng et al.(57)	YBCO pellet	annealed Ag epoxy	900°C	77K	<10 ⁻⁷ ←
Tzeng(58)	-	evaporated Au film	300°C	77K	$<7 \times 10^{-8}$ ←
Ekin et al.(52)	sputter-etched YBCO pellet	evaporated Ag film	-100°C	77K	6×10^{-6}
Ekin et al.(59)	-	evaporated Ag film	500°C	77K	4×10^{-8} ←
Mizushima et al.(60)	YBCO film	melted Ag bead	970°C	77K	<10 ⁻⁸ ←
Gavaler et al.(61)	YBCO film	sputtered Ag film	20°C	77K	10^{-5}
Jin (preprint, APL)	YBCO bulk	sputtered Ag film	500°C	77K	$<2 \times 10^{-9}$ ←
		evaporated Au film	600°C	77K	$<4 \times 10^{-10}$ ←
		evaporated Au film	850°C	4.2K	$<10^{-8}$ ←
		ex-situ evaporated Au film	20°C	10K	2×10^{-4}
		in-situ evaporated Au film	20°C	10K	$<4 \times 10^{-10}$ ←
		soldered Ag	800°C	77	$<2 \cdot 10^{-12}$ ←

the technology of making contacts is well established

high T resistivity of $\text{Ba}_2\text{YCu}_3\text{O}_7$, $\text{La}_{2-x}\text{Sr}_{x+0.5}\text{CuO}_4$



no saturation at high T $\Rightarrow \lambda_{\text{eff}} > a_0$, lattice spacing

$\Rightarrow \lambda_{\text{el-ph}} < 0.21$ BYCO

< 0.1 LSCO (ceramic)

similar to Cu, Au, Na, K, etc

Strong argument against phononic mechanism

Gurvitch et al. PR B
Flory et al.

- 12 -

linear $\rho(T)$ consistent with Bloch-Grüneisen:

Gottwick: BYCO $\rho(T)$ fitted with $\theta_0 = 350$ K

Micnas: B-G curvature decreased for small Fermi surface

Martin: B-G curvature seen in $\text{Ba}_2\text{YCu}_3\text{O}_7$

\Rightarrow linearity is striking but not exotic

however - Martin et al.: $\rho(T)$ $\text{Bi}_2\text{Sr}_2\text{CuO}_8$

linear down to 5K

\Rightarrow can't be Bloch-Grüneisen!

(?)

Gottwick ^{et al.} *Europhys Lett* 3 (1987) 483.
Micnas et al. PR B 36 (1987) 4051.

ANISOTROPIC CONDUCTIVITY

van der Pauw Philips Res. Rept. 16(1961)187

arbitrary shape 2D film can be mapped onto infinite half plane

Wasscher Philips Res Rept 16(1961)301

anisotropic mat'l can be mapped onto equivalent isotropic solid

Logan et al. JAP 42(1971)2975

calculate ρ for rectangular prism with contacts on corner of one face

Montgomery JAP 42(1971)2971

combine idea of Wasscher + calc's of Logan to infer anisotropic ρ

real dimensions l_1, l_2, l_3

resistivity $\rho_{11}, \rho_{22}, \rho_{33}$ diagonal components of ρ tensor

mapped dimensions l_1, l_2, l_3, ρ

$$\text{where } l_i \propto l_i' \cdot (\frac{\rho_i}{\rho})^{1/2}$$

$$\rho \propto (\rho_{11}\rho_{22}\rho_{33})^{1/3}$$

thus $1 \times 1 \times .05 \text{ mm } \text{Ba}_2\text{YCu}_3\text{O}_7 \quad (\rho_{ab}/\rho_c = 10)$

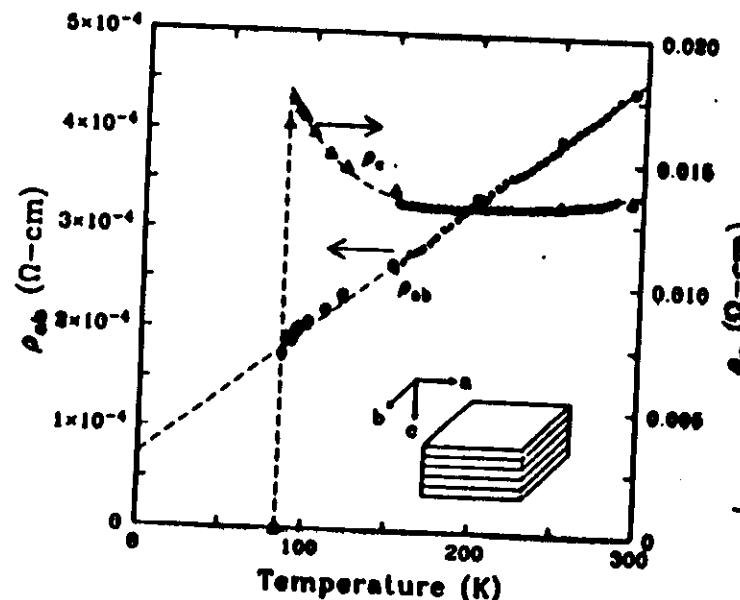
maps to $.68 \times .68 \times .11 \text{ mm}$



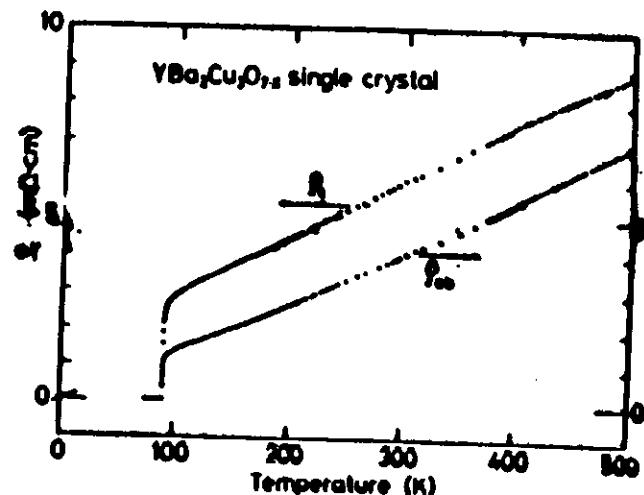
$\text{Ba}_2\text{YCu}_3\text{O}_7$

consensus on ρ_{ab}

controversy on ρ_c



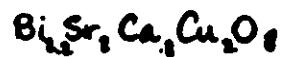
Toser et al.
PRL 57(1987)760



'typical of better
crystals'
(longer O₂ anneal)
 ρ_{ab} extrapolated to zero

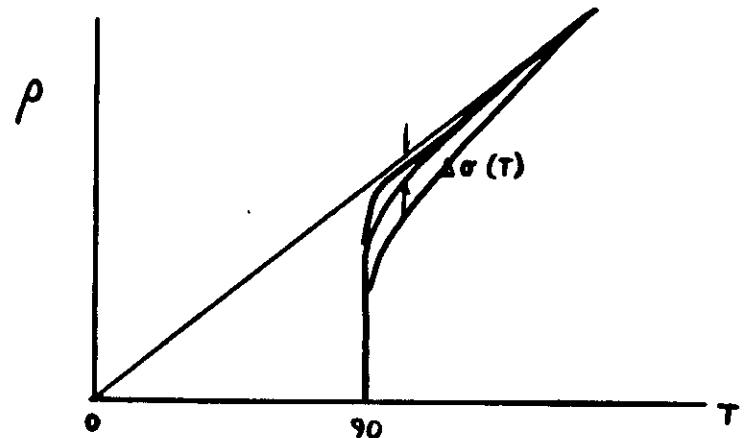
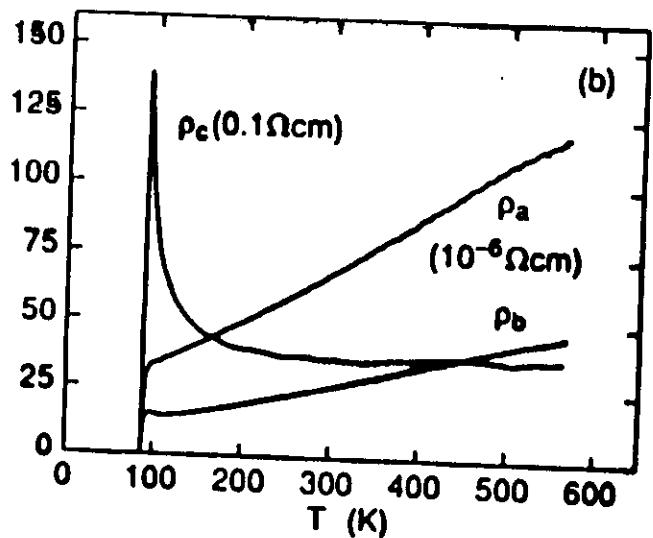
Iye et al.
JETP 37(1983)659

FLUCTUATIONS



$$\frac{\rho_c}{\rho_a} \sim 10^5 \quad \text{at } T = T_c$$

$1 \times 1 \times .001 \text{ mm}^3$ shd maps to $1 \times 1 \times .31 \text{ mm}$



spontaneous fluctuations above T_c lead to enhanced conductivity (and decreased susceptibility)

2D or 3D ? depends on $f_c(T)$, coupling along \hat{c}
 $\Delta\sigma(T)$ measurements not consistent

fitting to theory Aslamazov-Larkin + Maki-Thompson

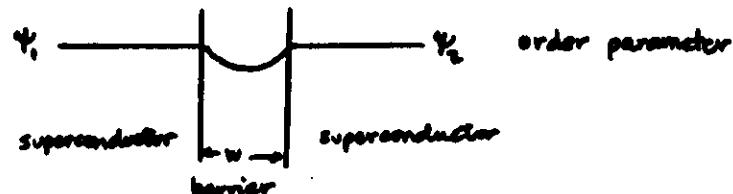
+ Zeeman term ? Aronov et al. PRL 62 (1989) 968
 (magnetoresistance)
 inhomogeneity ?

TRANSPORT MEASUREMENTS ON CERAMICS

- much easier to obtain than xta ls or high-quality thin films
 - although xta ls & films are hard to rot, ceramics are much harder

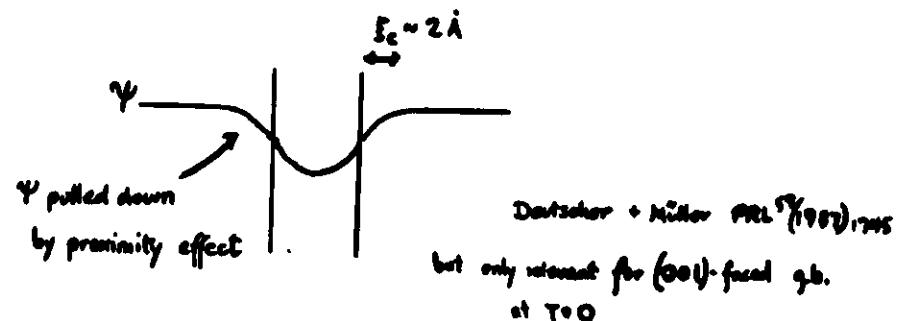
- percolation, connectivity, cf Cu-Bi embrittlement
 - B.T. Schlorshäuser + A.L. Efros
Electronic Prop. of Doped Semiconductors
effective medium theory

tunnel barriers

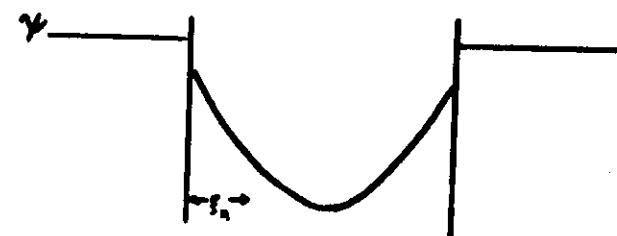


$$\text{coupling} \sim \Gamma_c \sim e^{-\omega k} \quad \begin{matrix} \text{length scale} \\ \kappa = (\alpha m \hbar / \lambda)^{1/4} \\ \omega \hbar \end{matrix}$$

$$\text{Ambagashar - Baratoff} \quad k_e R_n \sim \frac{\pi \epsilon}{2\delta}$$



$S-S'-S$ or $S-N-S$



- granular superconductors
 - more on this in discussion of j_c

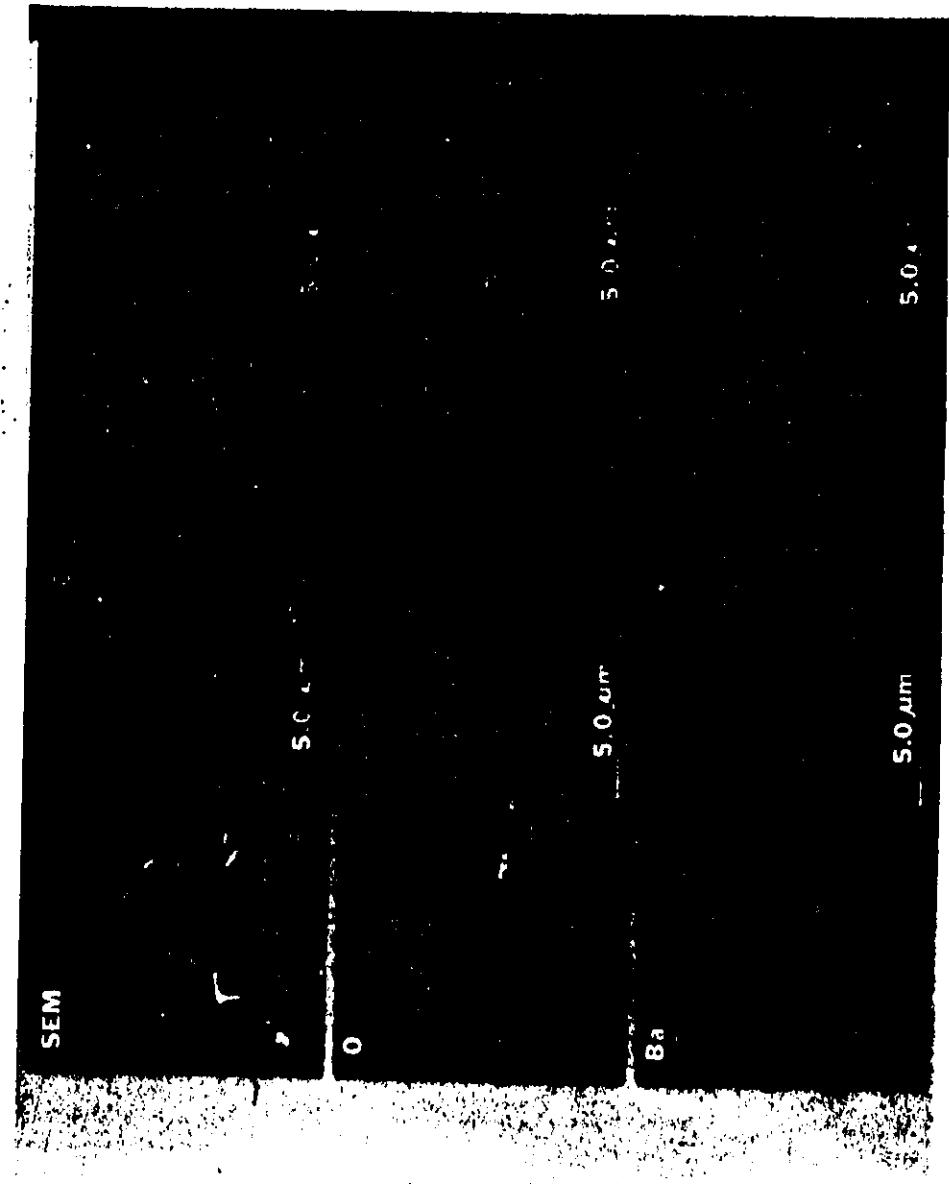
ORIGIN OF WEAK COUPLING

disorder

oxygen deficiency

intrinsic - due to anisotropy

extrinsic decoration ($\text{Ca}-\text{O}_2$)



AC response

LONDON TWO-FLUID MODEL

- simple
- qualitatively correct for $\omega < 2\alpha/k$ i.e. below gap frequency
- (no quantum mechanical aspect)

NORMAL STATE (Drude)

viscous charged fluid $q_1 \ll 1$ $k = \text{wavenumber of field}$
 $l = \text{mean free path}$

$$F = qE = m \frac{dv}{dt} \rightarrow \frac{mv}{\tau} \quad \tau = \text{scattering time}$$

$$\epsilon = \epsilon_0 e^{i\omega t}$$

$$\epsilon' = 1 + \omega\tau + \frac{mv}{\epsilon} \quad \sigma = \frac{J}{E} = \frac{nev}{\epsilon} = \frac{n\epsilon^2 c/m}{1 + i\omega\tau} = \sigma_i + i\sigma_n$$

$$\sigma_i = \frac{n\epsilon^2 c/m}{1 + \omega^2 \tau^2} \quad \sigma_n = \frac{(n\epsilon^2 c/m) \omega \tau}{1 + \omega^2 \tau^2}$$

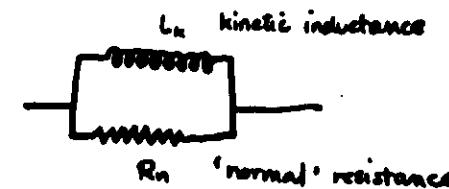
WHAT IF $\tau \rightarrow \infty$ $R = 0$ (non viscous)

$$\sigma_i = \frac{\pi n e^2}{m} \delta(\omega) + \frac{n e^2}{i m \omega}$$

TWO FLUID CONCEPT n_s, n_n

$$J = J_s + J_n \quad \sigma = \frac{\pi n_s e^2}{m} \delta(\omega) + \frac{n_s^2 e^2}{i \omega m} + \frac{n_n e^2 c/m}{1 + i \omega \tau}$$

equivalent circuit



NOTE: σ_n is not simply the normal-state resistivity extrapolated to the measurement temperature. it has a strong temperature dependence (at low T the 'normal' electrons, n_n , freeze out). σ_n must be measured for each mat'l individually.

response to ac magnetic field:

$$\frac{d}{dt} J_s = \frac{\eta e^2}{m} E \quad \text{London's 1st eqn}$$

$$\nabla \times B = \frac{4\pi}{c} J$$

$$\nabla \times E = -\frac{1}{c} \frac{\partial B}{\partial t}$$

$$\frac{\partial}{\partial t} (\nabla \times B) = \frac{4\pi}{c} \frac{n_s e^2}{m} E$$

$$\nabla \times [] = \nabla^2 \phi = \frac{1}{\lambda^2} \dot{\phi} \quad \lambda = \frac{mc^2}{4\pi n_s e^2} \quad \text{London penetration depth}$$

only screens changes: NOT MEISSNER EFFECT

$$\nabla^2 \vec{B} = \frac{1}{\mu_0} \vec{B}$$

screening changes in \vec{B}

thus ac susceptibility measurements measure
eddy current screening

χ' screening L_n or λ or $\text{Im } \sigma$

χ'' dissipation R_n or $\text{Re } \sigma$

MAGNETIC PENETRATION DEPTH

measure by γ SR

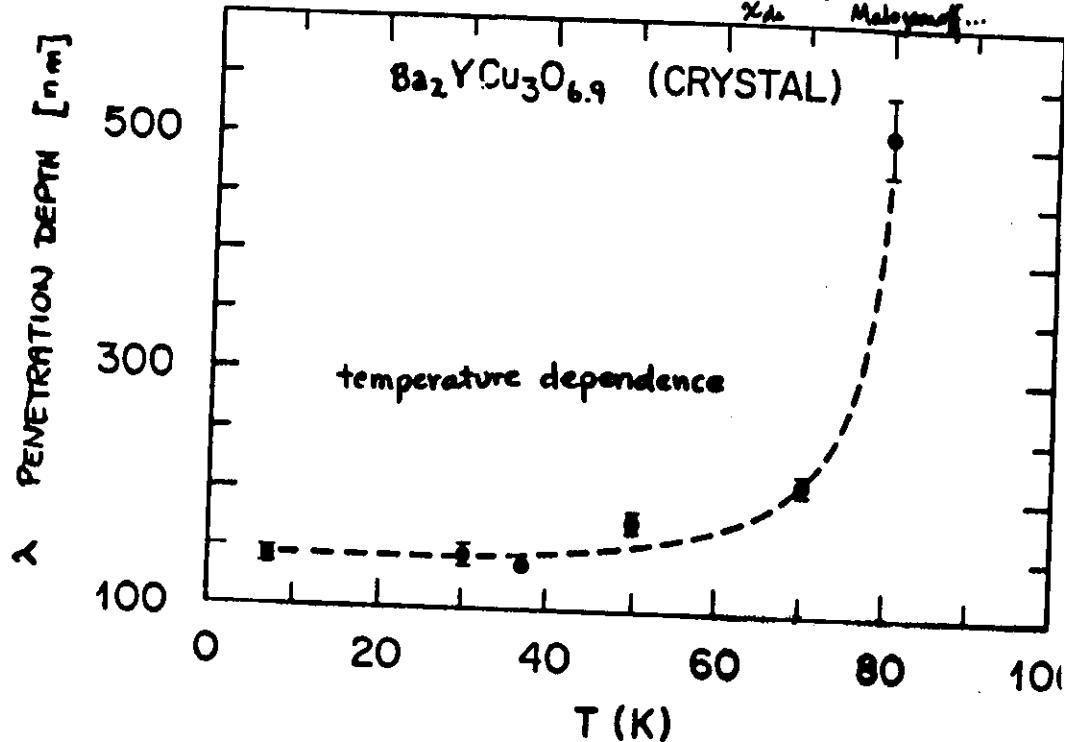
screening

χ_{de}

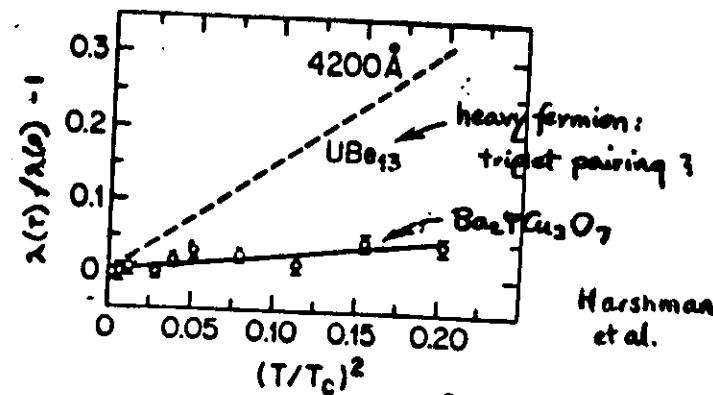
Hersman

Hebard

Meloyanoff...



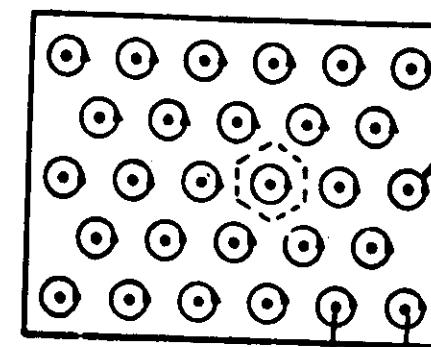
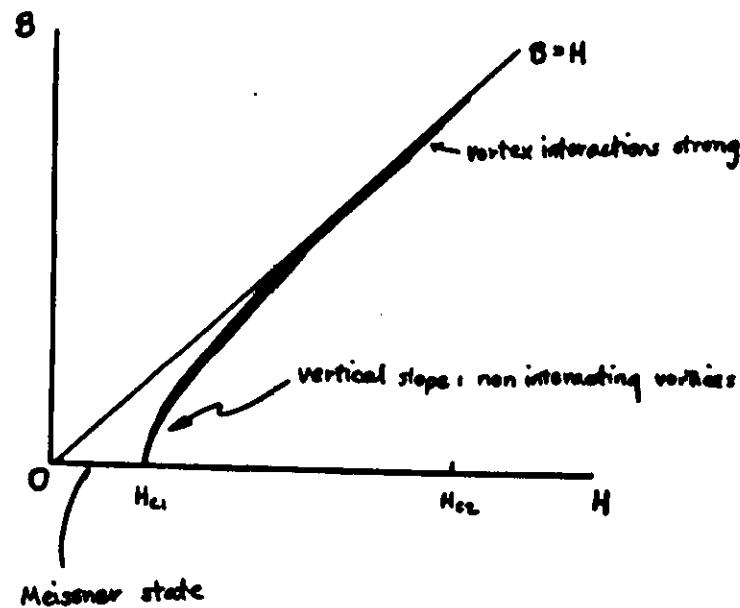
⇒ EVIDENCE FOR
SINGLET
PAIRING IN
 $\text{Ba}_2\text{YCu}_3\text{O}_7$



VORTEX STATE

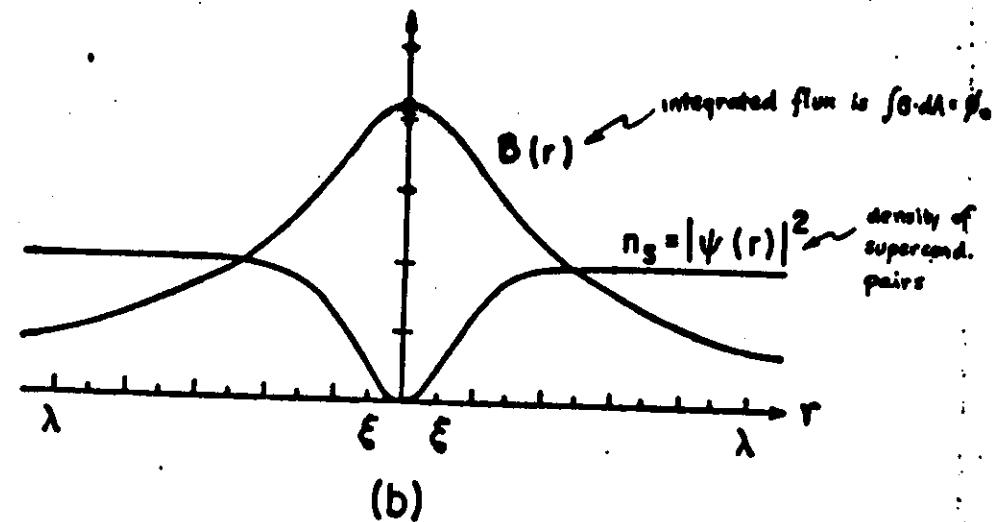
CONVENTIONAL
TYPE-II SUPERCONDUCTOR

CONSTITUTIVE RELATION $B(H)$

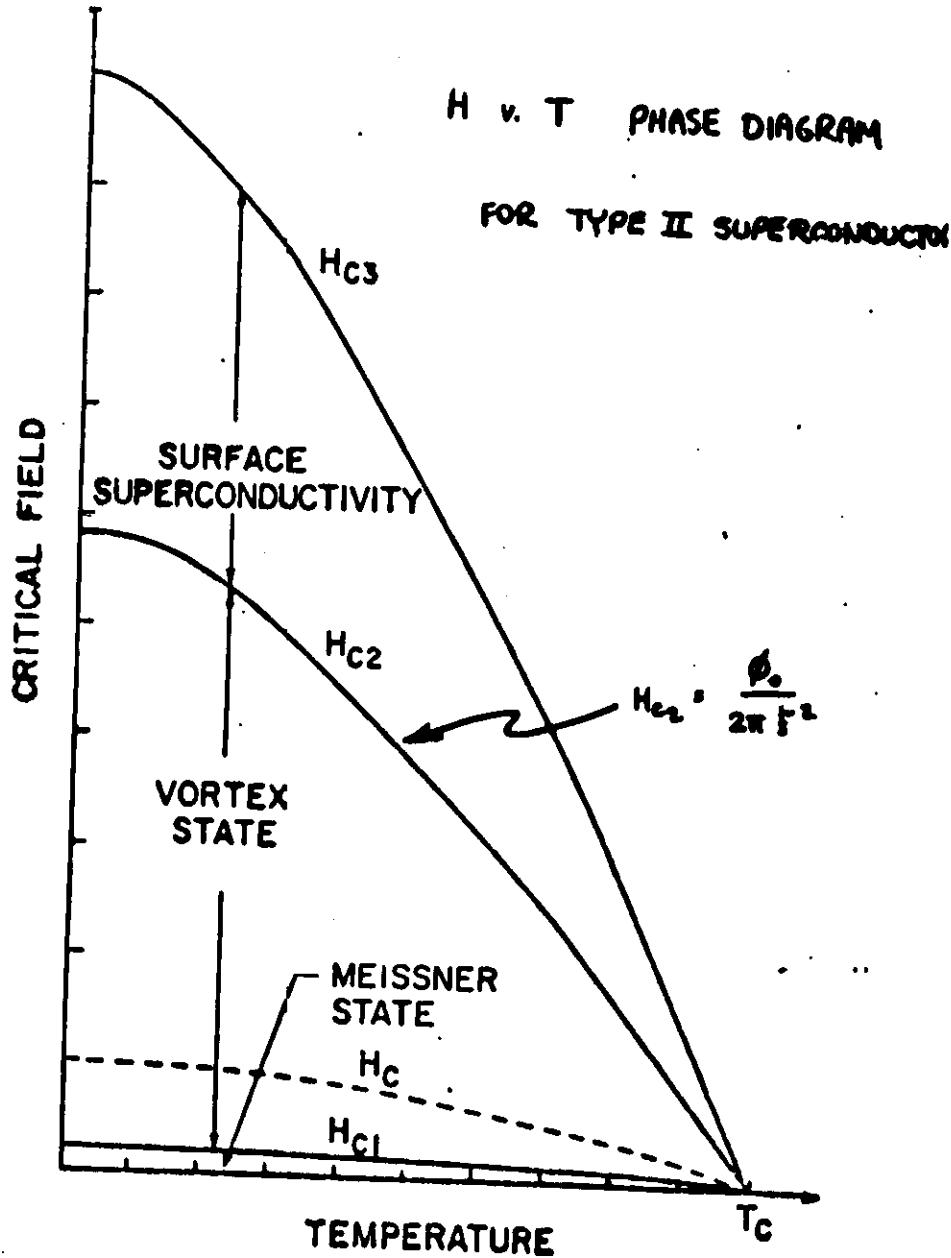


$$\text{flux threading each vortex} = \frac{\phi_0 \cdot h}{2e}$$

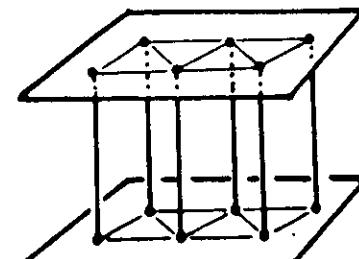
$$B = \frac{A}{a_0^2} \left(\frac{B_0}{a_0} \right)^2 = \frac{B_0}{65 a_0^2}$$



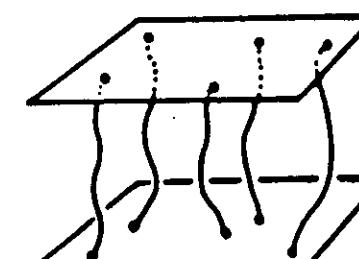
(b)



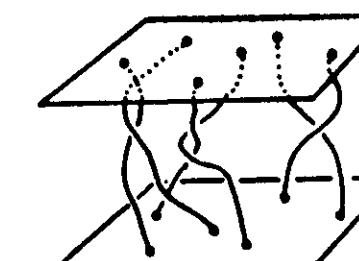
VORTEX ENTANGLEMENT



(a)



(b)



(c)

ABRIKOSOV
FLUX
LATTICE

low T

DISENTANGLLED
FLUX
LIQUID

thermal fluctuations important
e.g. $T = 77$, $H_c = 70$ G, $L = 11$
 $\Lambda_{rms} = 2.8$ μm

ENTANGLED
FLUX
LIQUID

Figure 7

Nelson PRL 60 (1986) 1973

Nelson + Seung PRB (preprint)

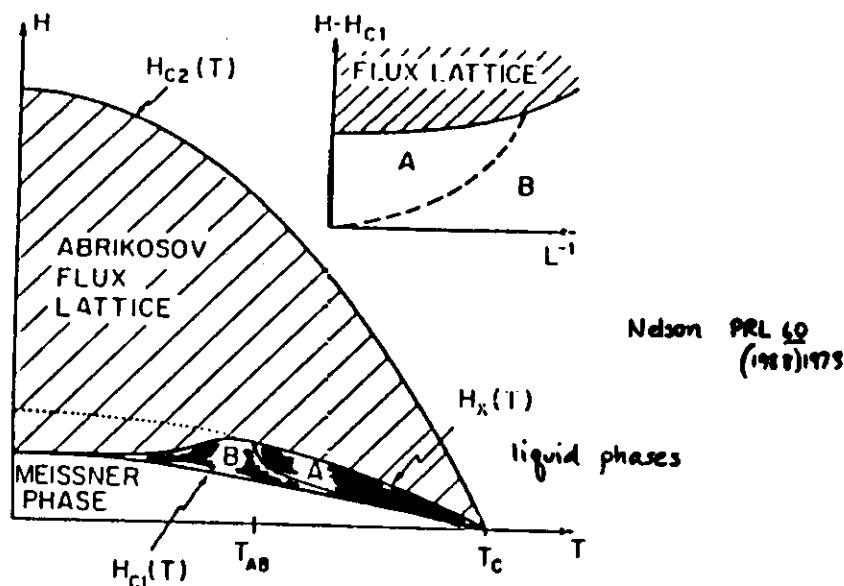


FIG. 1. Abrikosov flux lattice (shaded), entangled-flux liquid (*A*), and disentangled-flux liquid (*B*) phases as a function of H , T , and L^{-1} .

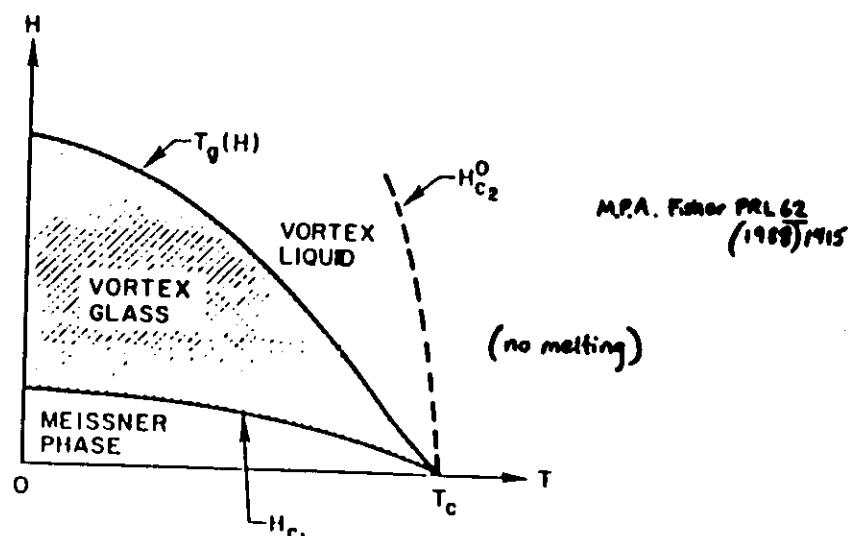


FIG. 1. Schematic phase diagram for a bulk dirty superconductor

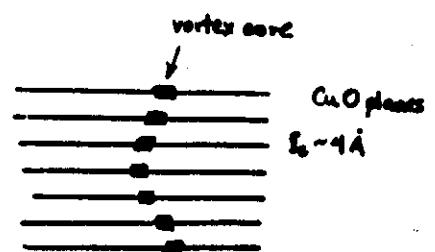
VORTEX ENTANGLEMENT + MELTED FLUX LATTICE

issues

boundary conditions (toroidal geometry)

strong sample thickness dependence $\eta \sim L^3$

effect of strong anisotropy



what is correlation length?

energy cost for lateral translation / when anisotropy & coupling

EXPERIMENTAL ISSUES

distinguish between kinetic transition and phase transition

RESISTIVE TRANSITION IN A FIELD

H_{c2} phase boundary

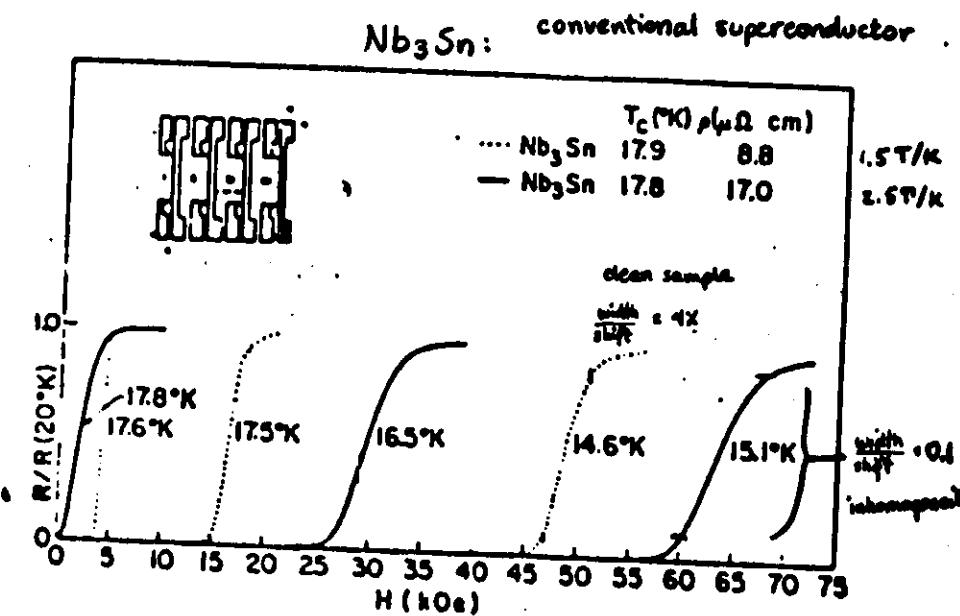
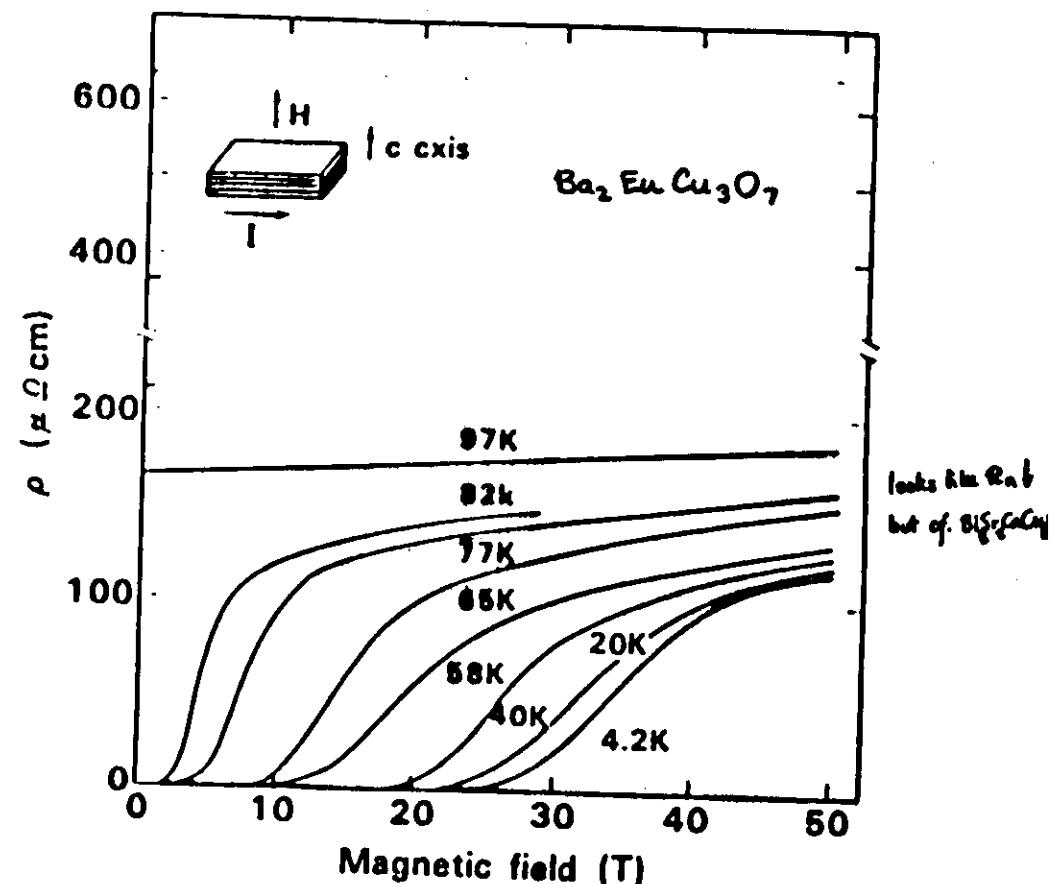
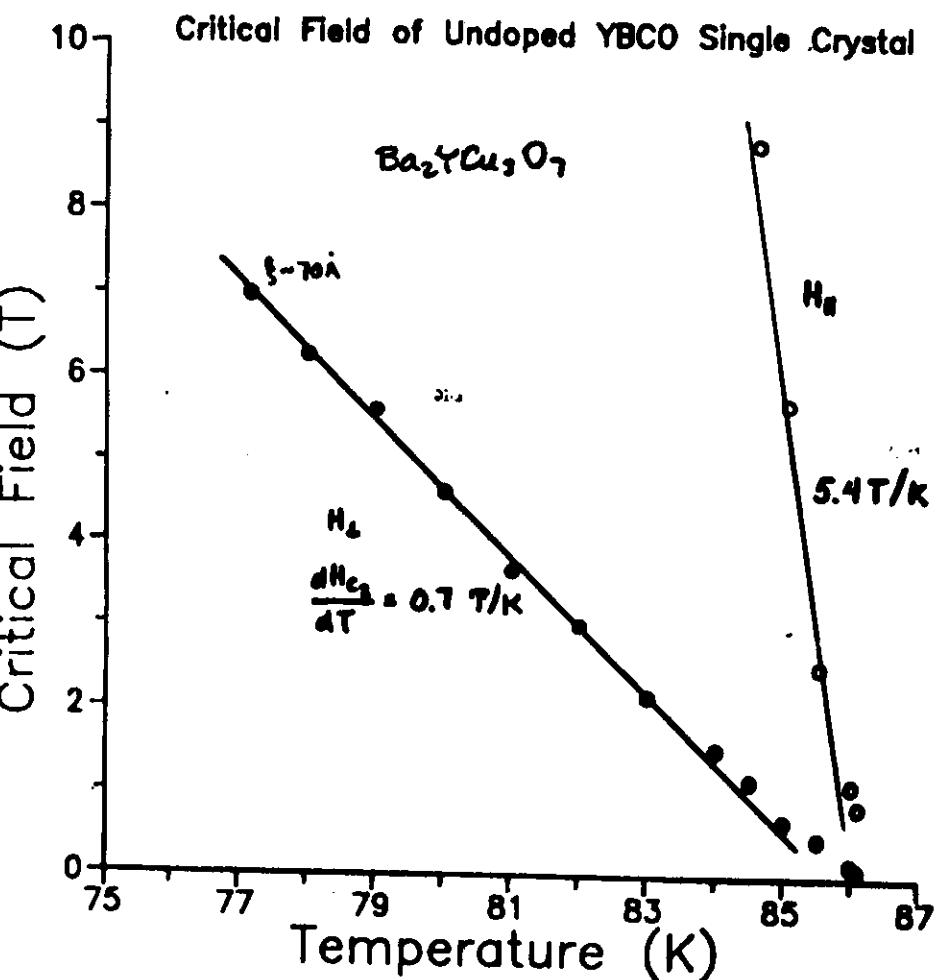


FIG. 1. Resistive transitions of Nb_3Sn thin films using field sweeps at constant temperatures. The sample (dotted

COMPARE TO HIGH- T_c SUPERCONDUCTOR



using $\rho_{n/2}$ resistance criterion

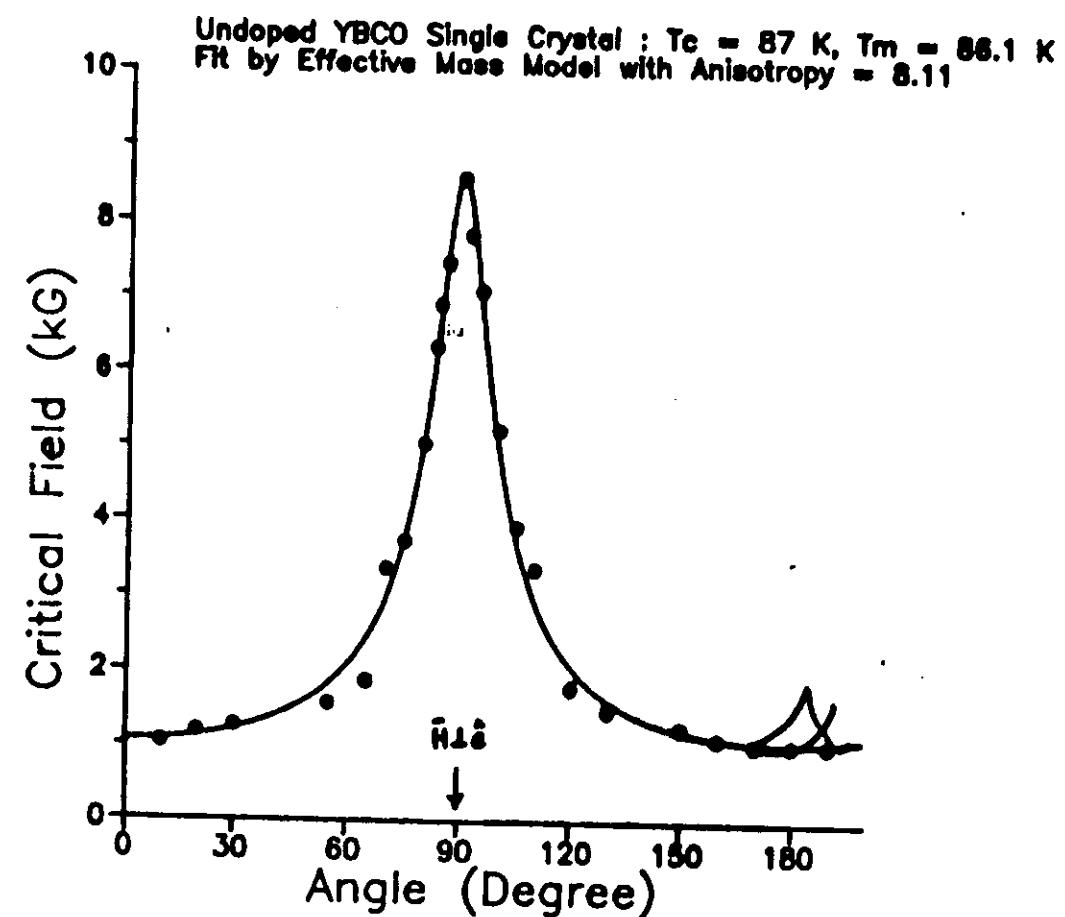


van Dover et al. PR 22 (1979) 29

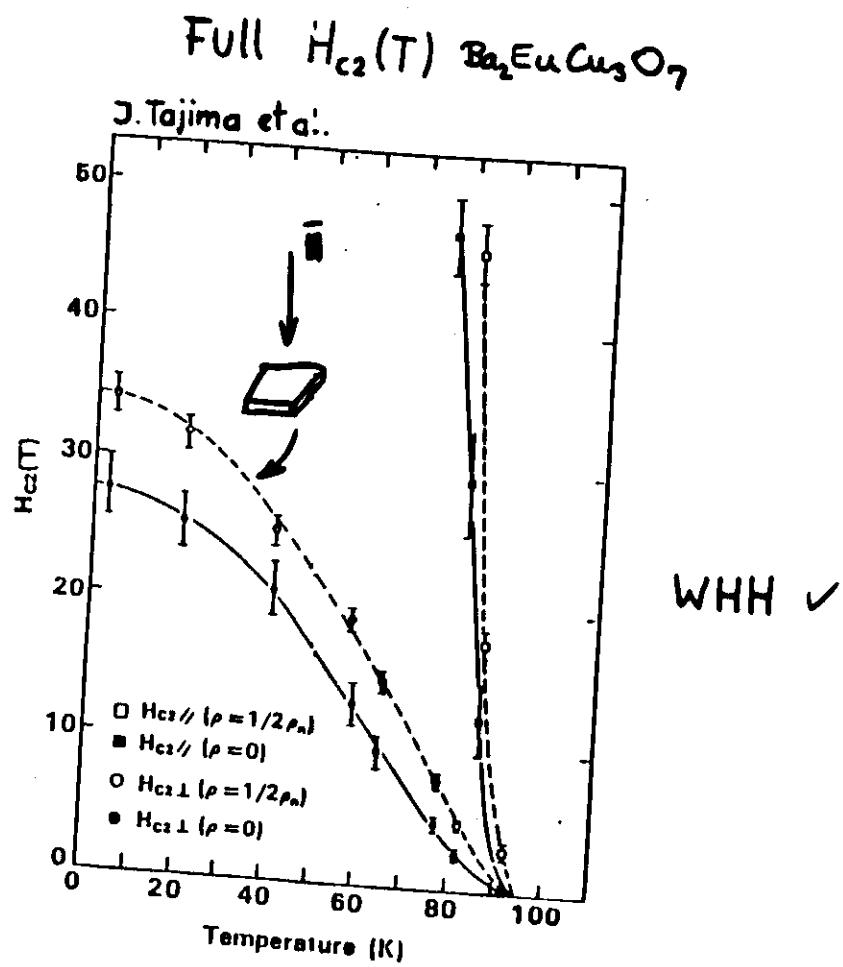
ANGULAR DEPENDENCE

fitted with GLAG-based effective mass model

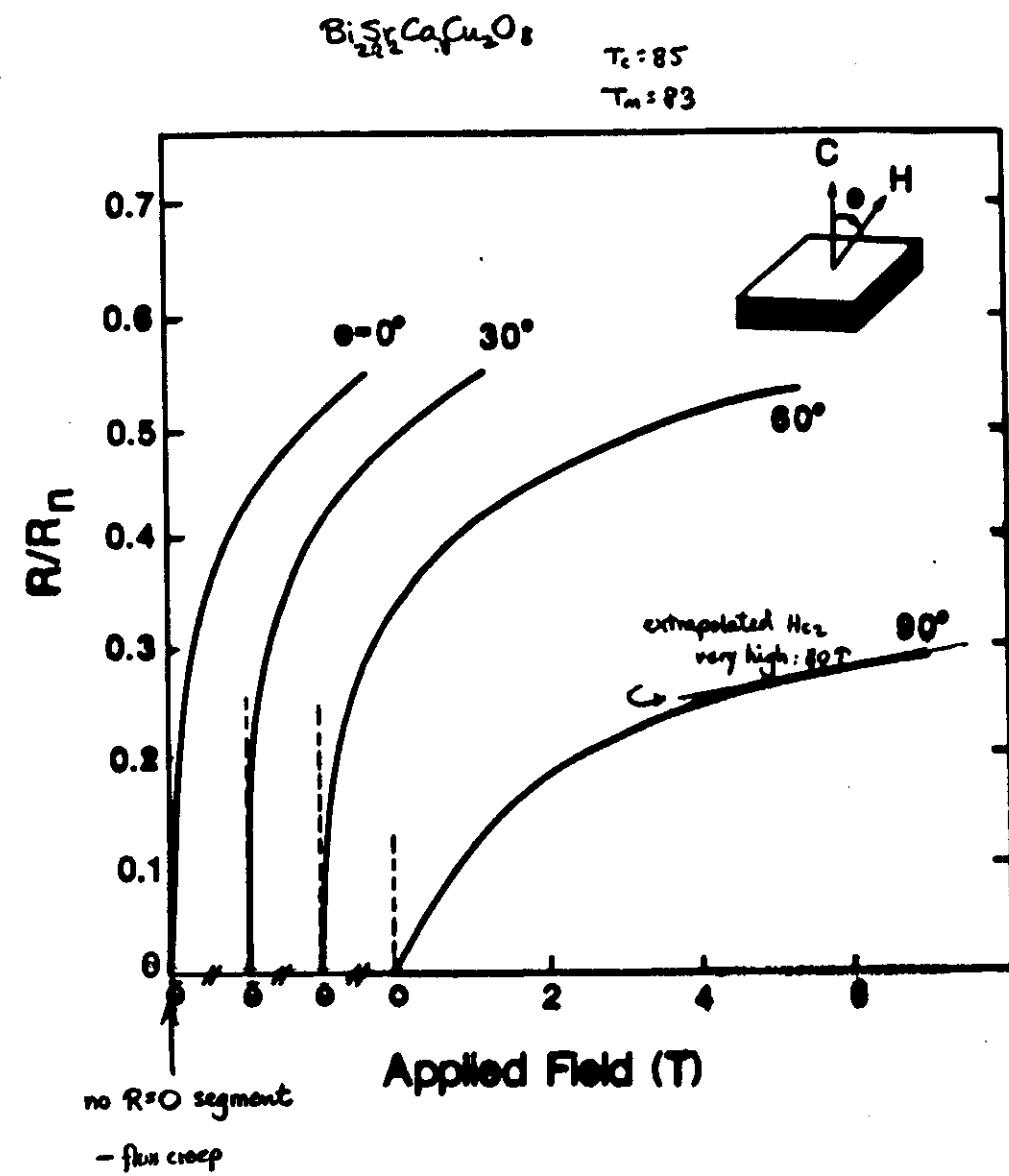
(doesn't fit 2-D model - due to coupling in c direction)



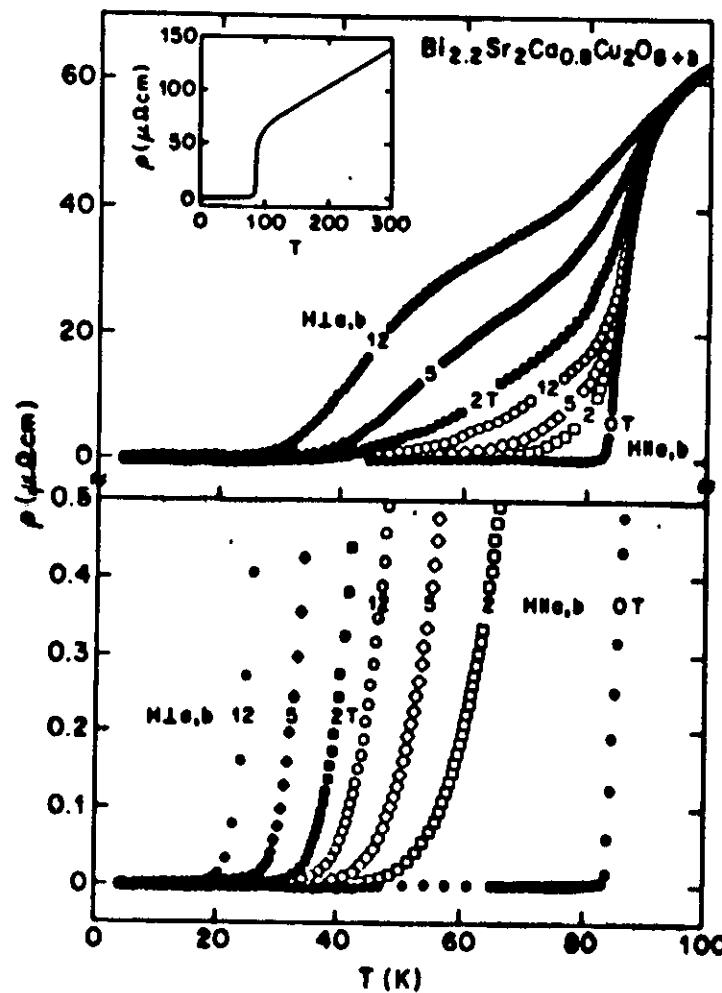
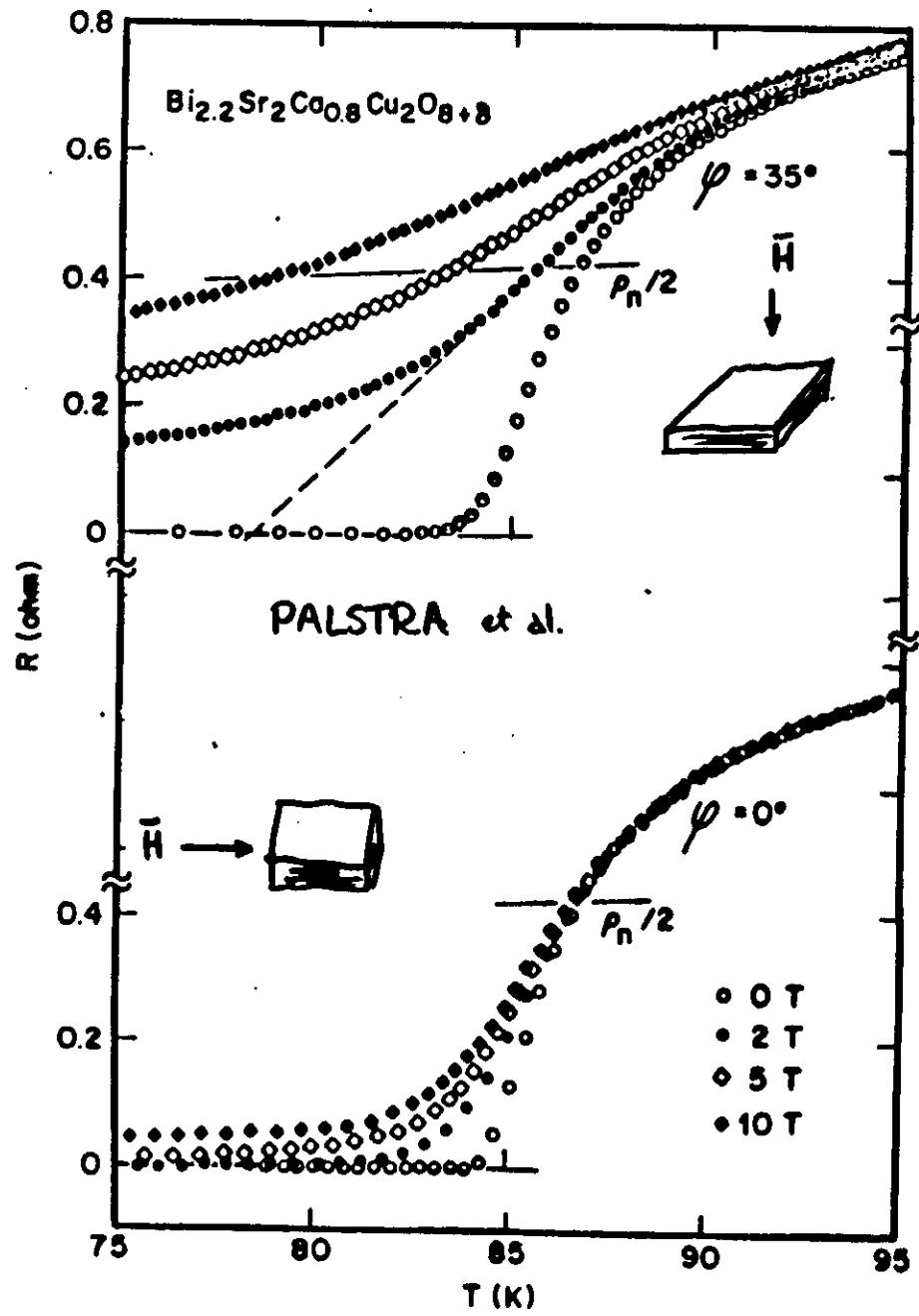
van Dover et al. (unpublished)



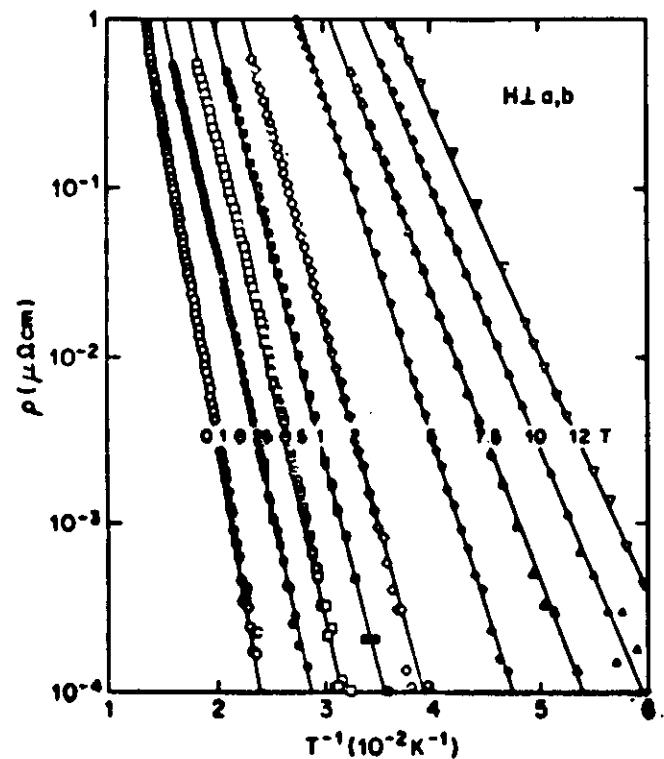
Werthamer-Helfand-Hohenberg
PR 157(1964)295
Tajima et al. PRB37(1988)7956



Jiang et al. PR 339(1984)

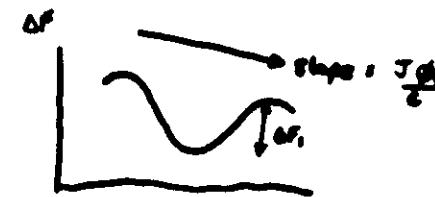
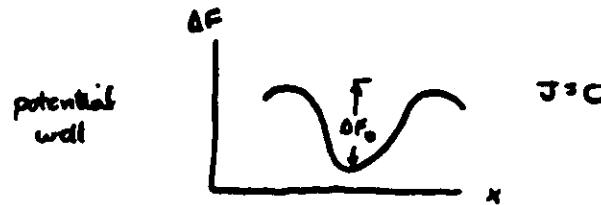


flux creep: Arrhenius law $\rho = \rho_0 e^{-U(H)/kT}$



DISSIPATION LIMITED BY THERMALLY
ACTIVATED HOPPING OUT OF FLUX PINNING
CENTERS

FLUX CREEP



$$\Delta F_i = \Delta F_0 - \frac{Jd_0}{e} \Delta x \quad \text{width of barrier}$$

net prob. of jump

jump time

$$P \propto e^{-\frac{\Delta F_i}{kT}} \left(e^{\frac{2\pi d_0 q_e}{kT}} - e^{-\frac{2\pi d_0 q_e}{kT}} \right)$$

$$\frac{Jd_0}{e} \rightarrow \frac{JBV}{e} \quad BV = \text{flux bundle} = n\phi_0$$

in MKS

$$\rho = \frac{2V_0 \Delta x B}{J} e^{-\Delta F_0/kT} \sinh \left(\frac{JBV \Delta x}{kT} \right)$$

$$\text{for } \frac{JBV \Delta x}{kT} \ll 1 \quad \rho = 2V_0 B^2 V_0 M e^{-\Delta F_0/kT} / kT$$

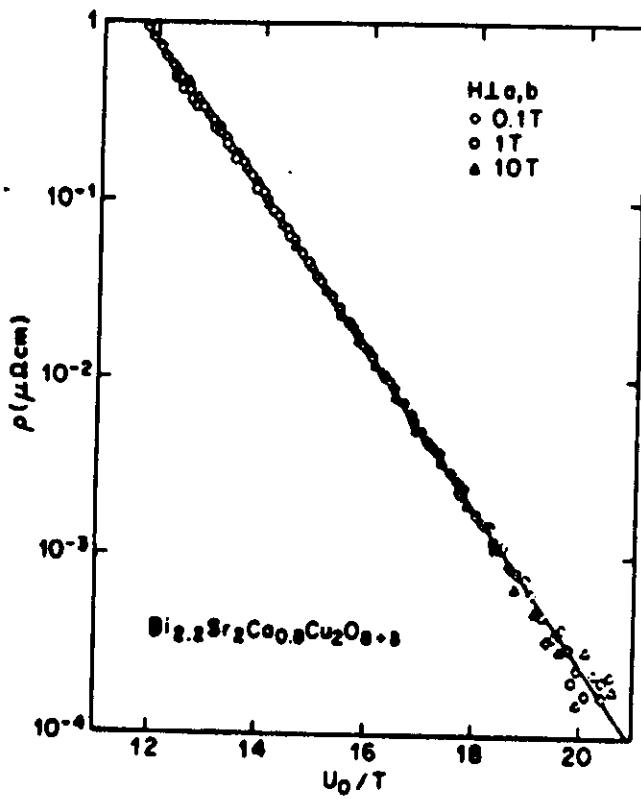


FIG. 3. Universal behavior of the thermally activated electrical resistivity for the data of Fig. 2 by use of a normalized temperature scale U_0/T .

18. ρ_0 independent of H

FIELD DEPENDENCE of ACTIVATION ENERGY

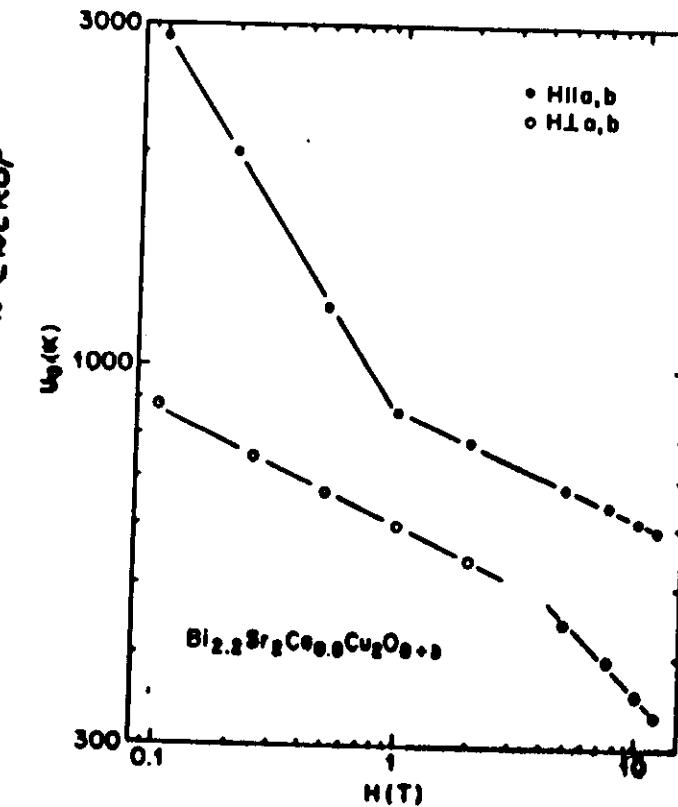
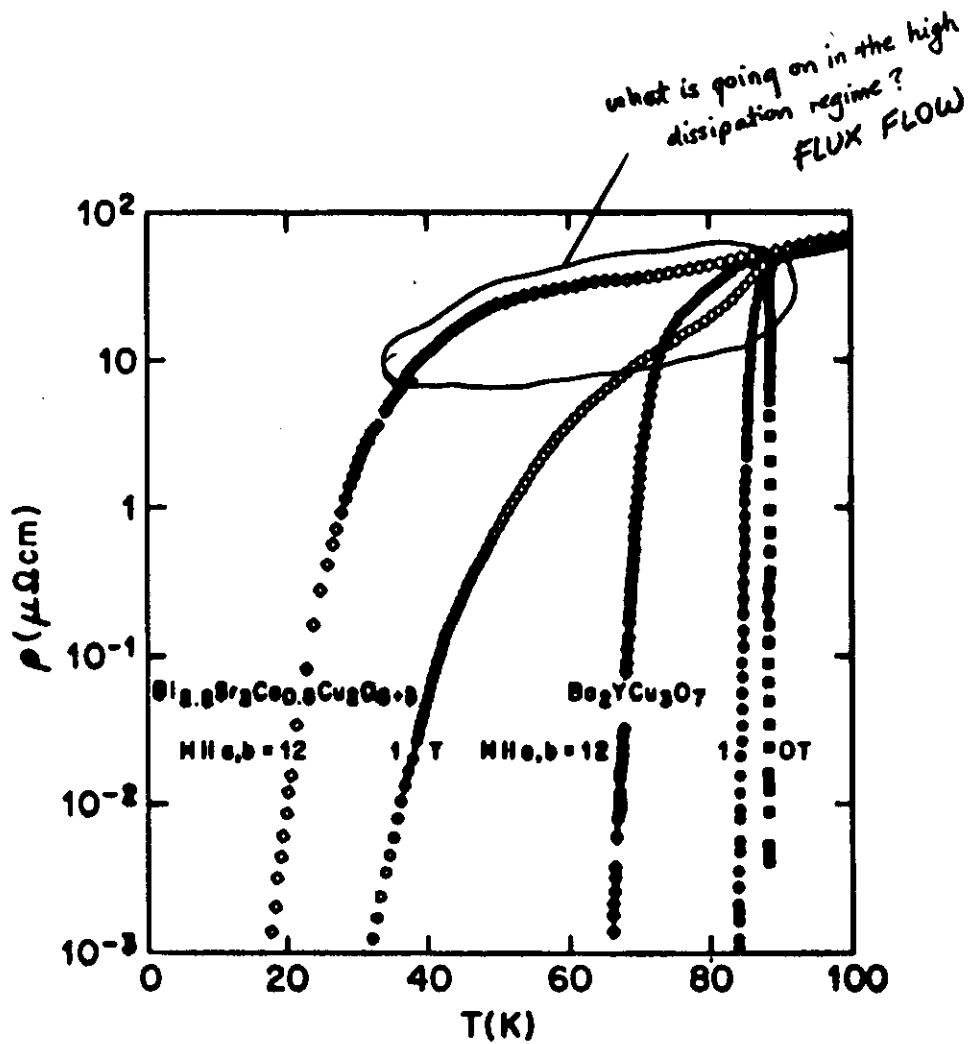


FIG. 4. Magnetic field dependence of the activation energy U_0 of $\text{Bi}_{2.2}\text{Sr}_2\text{Ca}_{0.9}\text{Cu}_2\text{O}_{8+\delta}$ in two orientations. The linear portions of the data suggest power laws $U_0 \sim H^{-\alpha}$ with $\alpha = \frac{1}{2}$ and $\frac{1}{4}$ for H_\perp and $\alpha = \frac{1}{2}$ and $\frac{1}{4}$ for H_\parallel .

cf activation energy inferred by
Yeshenko + Malozemoff PRL 61(1988)1662



FLUX FLOW RESISTIVITY - THEORY

① Bardeen - Stephen

Joyce heating in core, Maxwell eqns

3 low land excitations in core

$$\frac{\rho_f}{\rho_n} = \frac{B}{H_{c2}}$$

② Tinkham

Hu-Thompson

TGSL (gapless)

relaxation of order parameter

$$\frac{\rho_f}{\rho_n} = \alpha \cdot \frac{B}{H_{c2}}$$

Gorkov - Kapitza

(dirty)

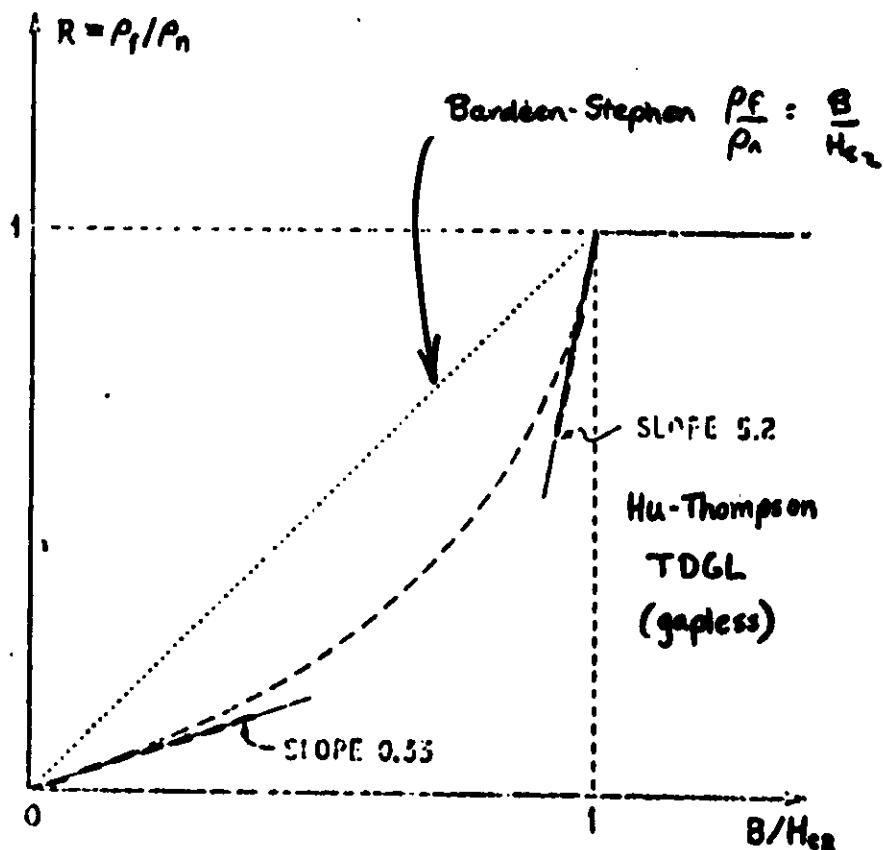
Ehrenberg kinetic equation

$$\frac{\rho_f}{\rho_n} = \frac{1}{\beta(T)} \frac{B}{H_{c2}(T)}$$

$$\beta(T) = \frac{1}{(1-t)^{1-\gamma}}$$

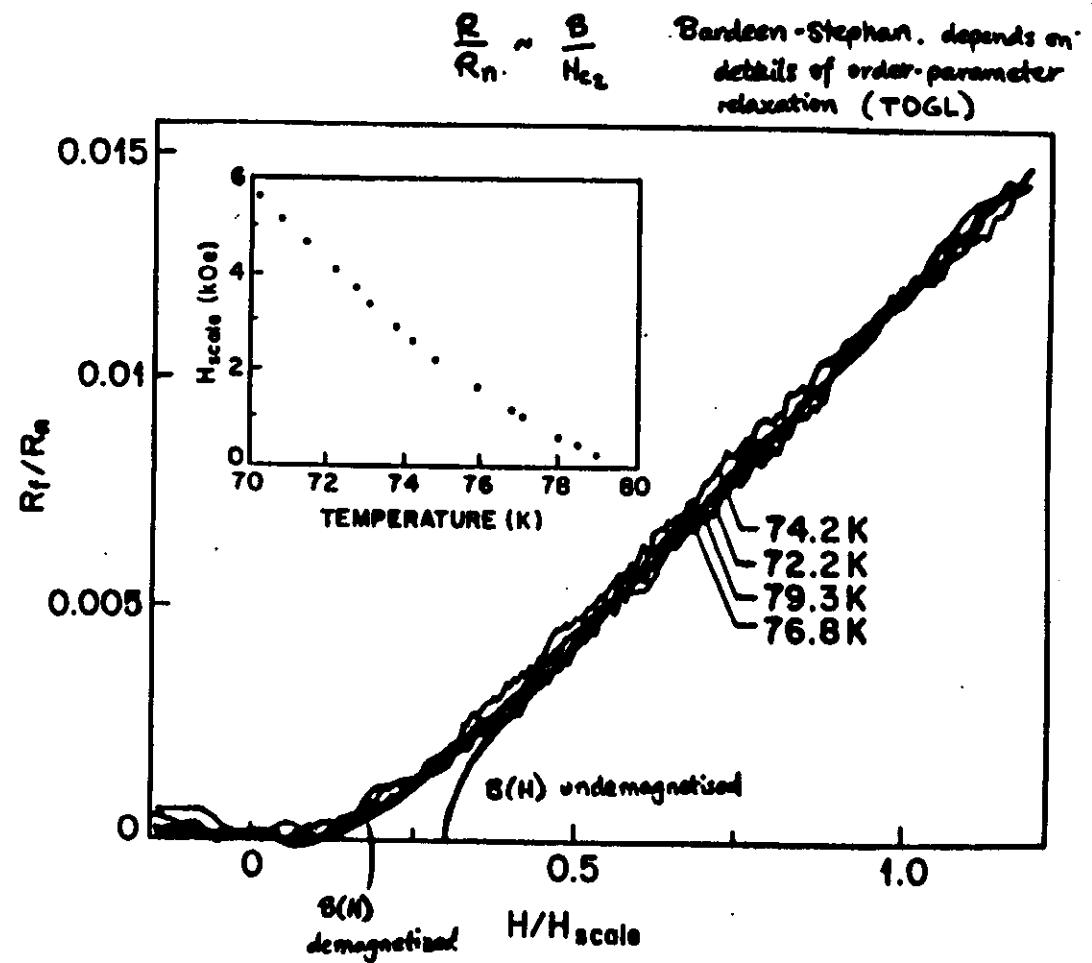
expts: Takayama $\beta(T) \sim (1-t)^{\gamma_1} \quad t < 0.9$
 $\quad \quad \quad \quad \quad (1-t)^{\gamma_2} \quad t > 0.9$

FIELD DEPENDENCE



FLUX FLOW REGIME

i.e. viscosity-limited flow



	<i>this work</i>	<i>Palstra, et al. (Ref. 10)</i>
$H'_{c1\parallel}$	100 Oe/K	$\rightarrow \lambda(0) \sim 300 \text{ \AA}$ n.a.
$H'_{c2\parallel}$	14 kOe/K	$\leftarrow 7.5 \text{ kOe/K}$
κ_{\parallel}	13.5	n.a.
H'_{\perp}	740 Oe/K	$\leftarrow 280 \text{ Oe/K}$
$H'_{c1\perp}$	2.1 Oe/K (*)	2.1 Oe/K
$H'_{c2\perp}$	2000 kOe/K	450 kOe/K
κ_{\perp}	1900	1000

PINNING

total free energy depends on position of vortices
 due to local fluctuations in material properties

- ① system seeks to sit at minimum total free energy
- ② so it takes energy to move vortices out of position
- ③ moving vortices \longleftrightarrow dissipation
- ④ pinning \longrightarrow critical current

in a sample which is perfectly uniform (e.g. single crystal & no defects)
 vortices are free to move $\Rightarrow j_c \rightarrow 0$

examples of pinning

low field (vortices well-separated, non-interacting)

e.g. core pinning

e.g. normal core sitting on a void is lower energy than normal core where superconductor must be driven normal

e.g. magnetic pinning

image of vortex located at sc./non sc. boundary
 \Rightarrow attractive potential

high field - need to do a full G-L analysis

see Campbell + Evets

Adv in Phys 21 (1972) 199

pinning of a single vortex

line energy of a fluxoid ($K \gg 1/\beta_L$)

$$F = \frac{\phi_0}{4\pi\lambda^2} \ln K + \frac{H_c^2}{8\pi} \pi s^2 = \frac{H_c^2}{8\pi} (4\pi s^2 \ln K + \pi s^2)$$

perturb $\frac{H_c^2}{8\pi}$ (condensation energy), F , $\ln K$

\Rightarrow perturbation in F

strength of pinning depends on subtleties

$$\text{typical } p = \frac{\delta F}{F} \sim 10^{-3}$$

NEED TO RELATE THE BASIC PINNING FORCE TO THE

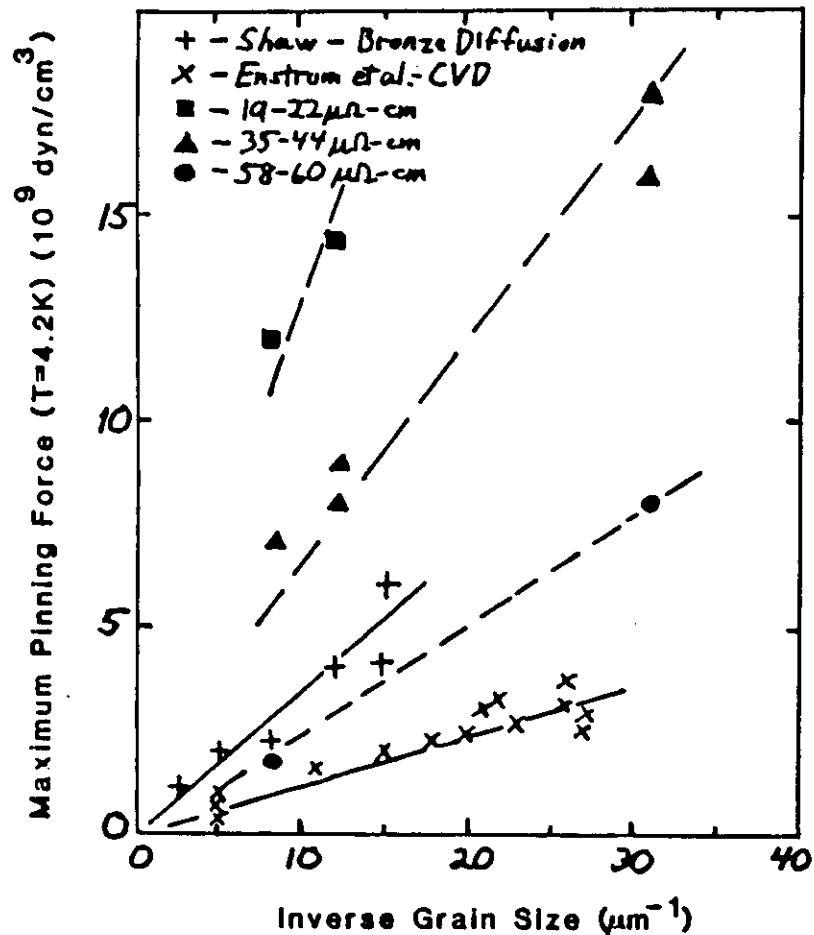
NET CRITICAL CURRENT:

"the summation problem"

see Campbell + Evets

details of elasticity of flux line lattice are important

pinning by grain boundaries
in Nb₃Sn



PINNING IN HIGH T_c MATERLS

$\text{Ba}_2\text{YCu}_3\text{O}_7$ twins?

o - vacancies?

grain boundaries?

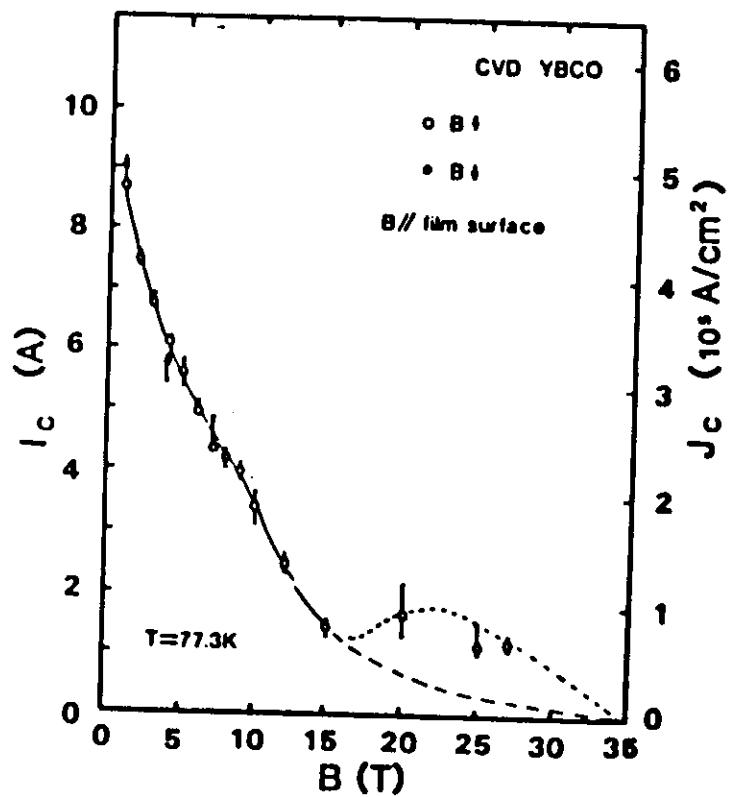
$\text{Bi}_2\text{Sr}_2\text{Ca}_2\text{Cu}_3\text{O}_{10}$ no twins.

intergrowths?

Figure 5.2: Maximum pinning force versus inverse grain size at 4.2K for samples grouped by their resistivity.

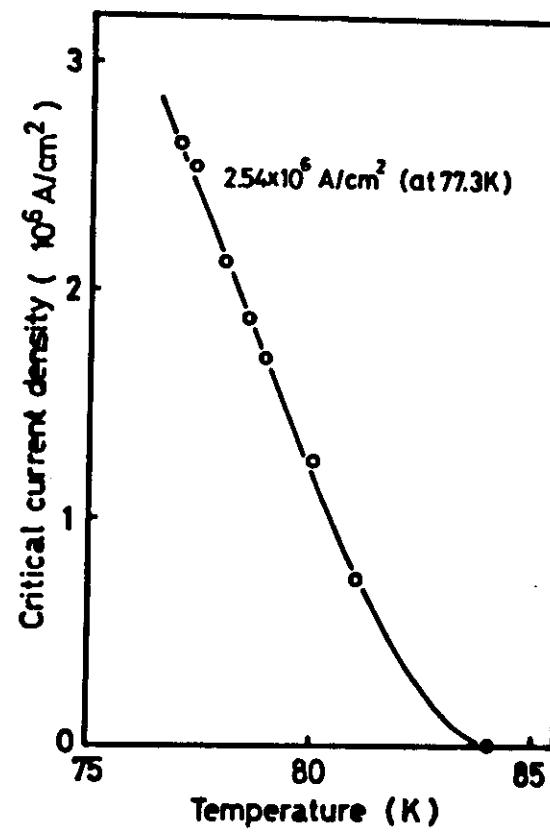
$\text{Ba}_2\text{YCu}_3\text{O}_7$ CVD

thin film: $\sim 1 \mu\text{m}$ thick but very porous
high density of oxygen空 boundaries

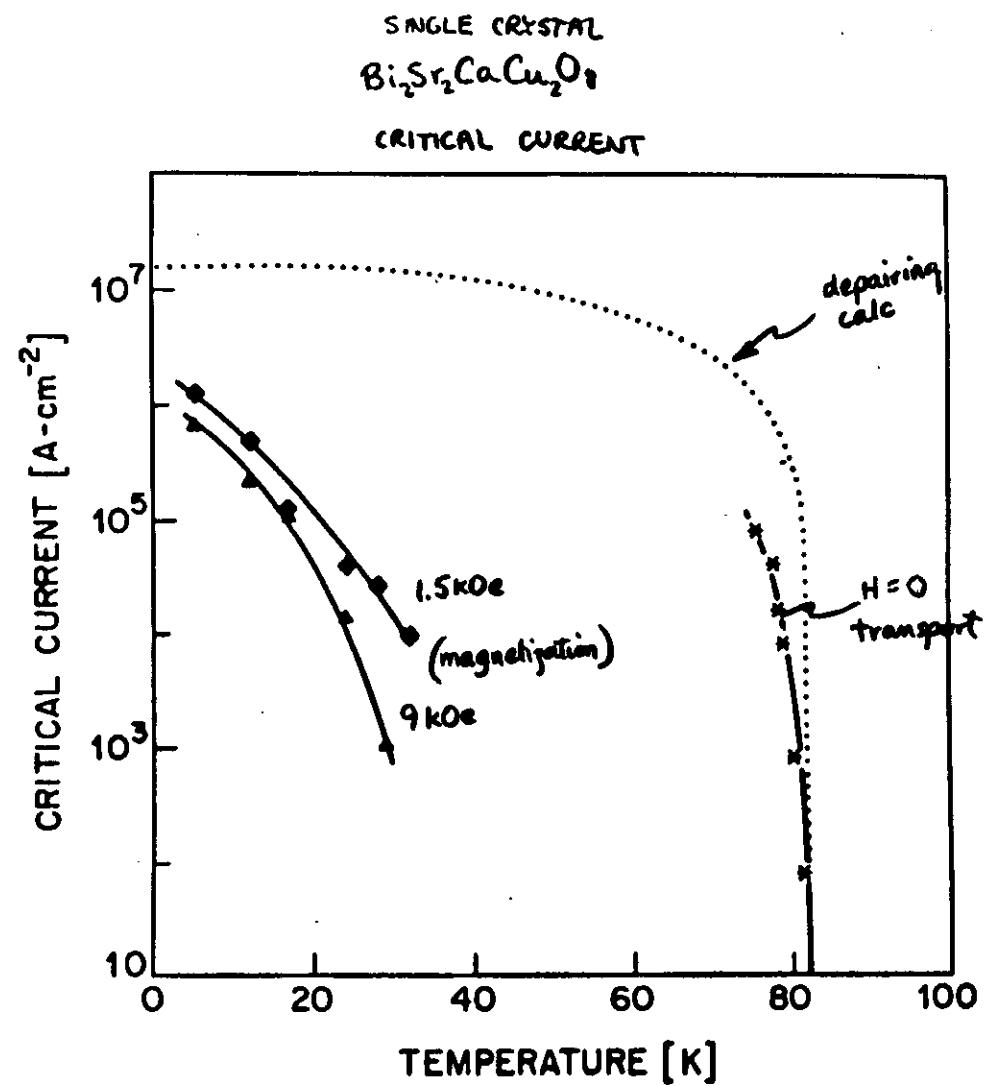
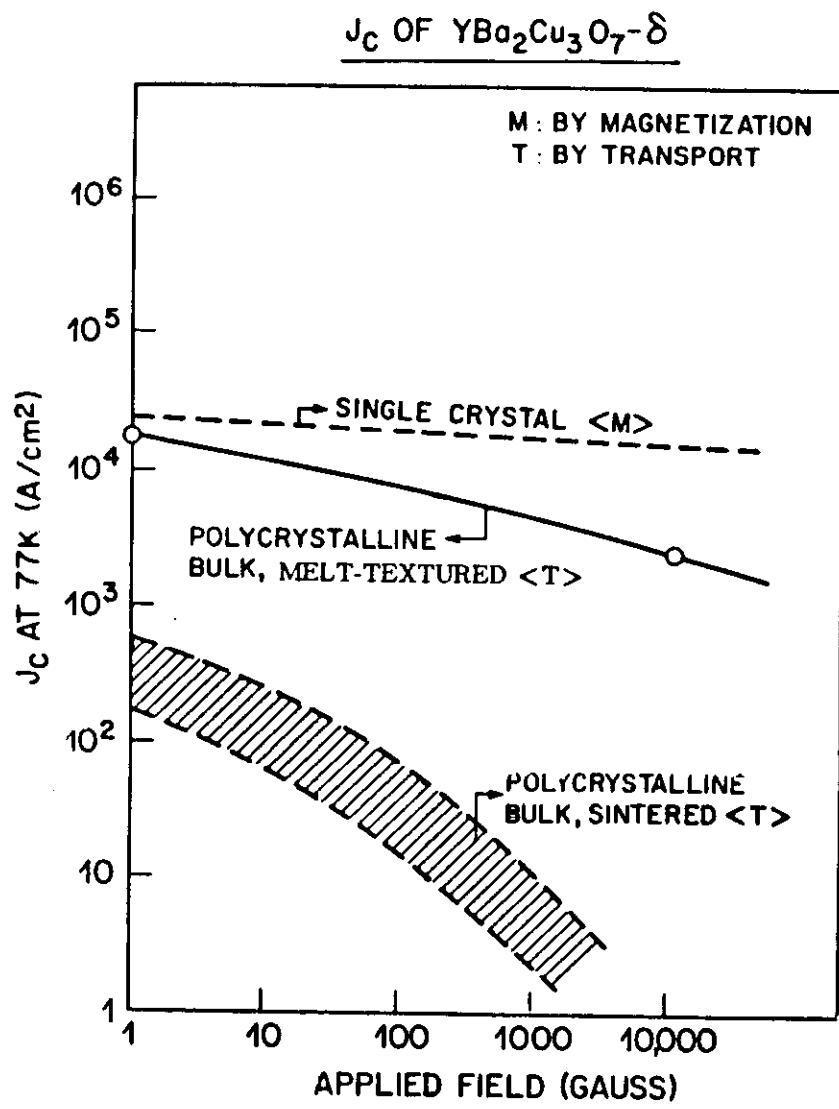


Watanabe et al. APL 54(1989)52

$\text{Ba}_2\text{HoCu}_3\text{O}_7$ evap



Tanaka et al. JJAP 27(1988)L622

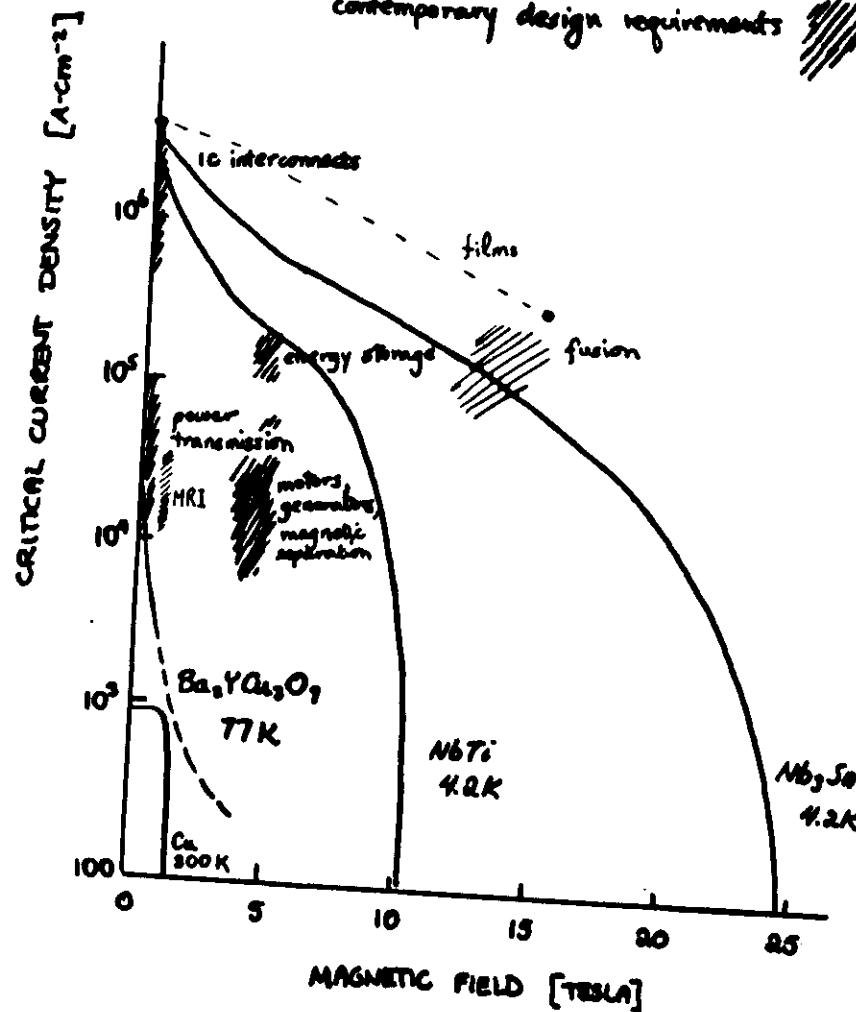


$H=0$ satoke law ($H = H_{ci}$ on surface
— depends on demagnetization

MAGNETIZATION LOOPS, CRITICAL STATE
& THE BEAN MODEL

PERFORMANCE REQUIREMENTS
FOR APPLICATIONS

contemporary design requirements



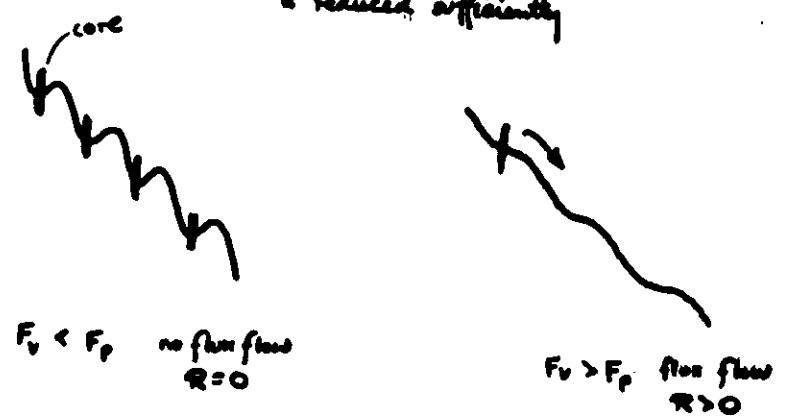
CRITICAL STATE MODEL

force on a single fluxoid $F = \frac{\bar{J} \times \bar{B}}{c}$

driving force density $F_D = \frac{\bar{J} \times \bar{B}}{c}$ $\bar{J} \times \bar{B}$ are average over 'small' volume

critical state: balance pinning force density with driving force density

i.e. fluxoids will move until driving force density is reduced sufficiently



critical current

$$J_c = \frac{c F_p}{8} \quad \text{actually, use this to define } F_p$$

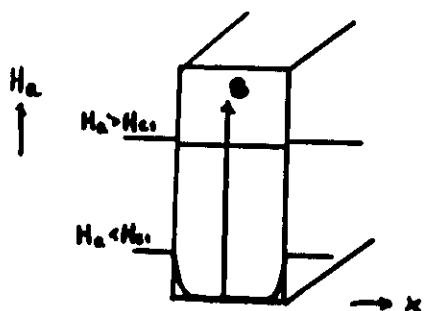
Bean model (use for calc'ns)

$$J_c = \text{constant up to } H_{c2} \quad (\Rightarrow F_p \propto B)$$

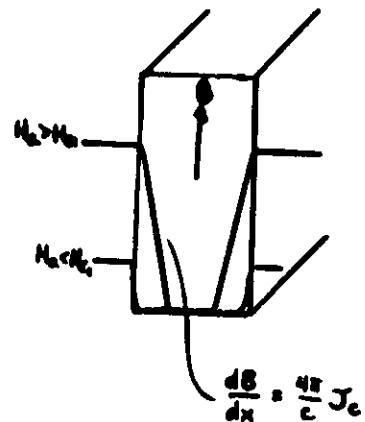
$$\text{could also use Anderson Kim} \quad J_c = \frac{a}{B r B_0} \quad (\text{if } F_p = \text{const})$$

$$\text{Rao Kumar + Chaddah} \quad J_c = J_{c0} e^{-H/H_0}$$

NO PINNING:



PINNING:

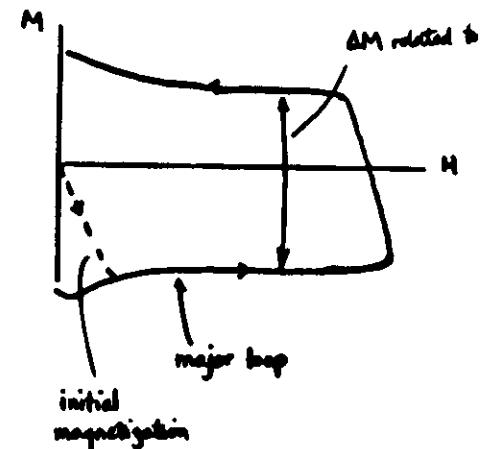


magnetization irreversible

M-H loops

NO PINNING:

reversible



ΔM a measure of J_c

Bean model

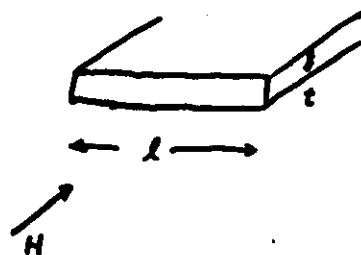
analogous to piling sand on the surface under question

slope of sand (\pm angle of repose) $\sim J_c$

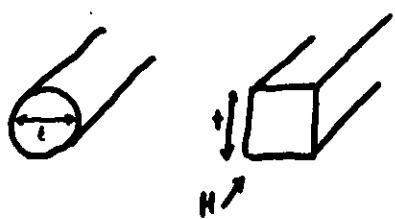
height of sand \sim internal field resulting from current flow

$\frac{\text{volume of sand}}{\text{area of base}}$ \sim magnetization M from current flow

examples

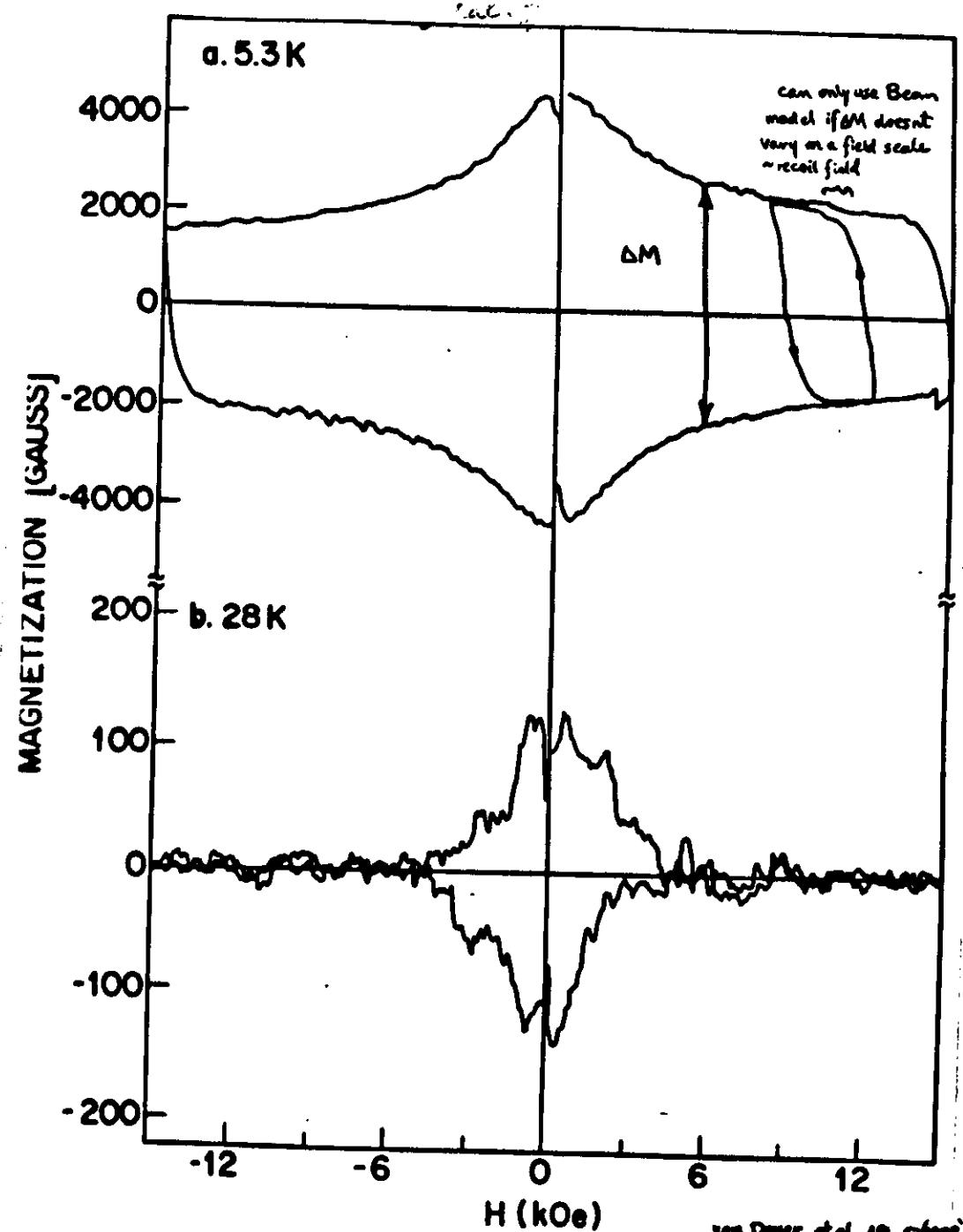


$$\Delta M = \frac{J_c t}{20} \text{ A/cm}^2 \cdot \text{cm}$$



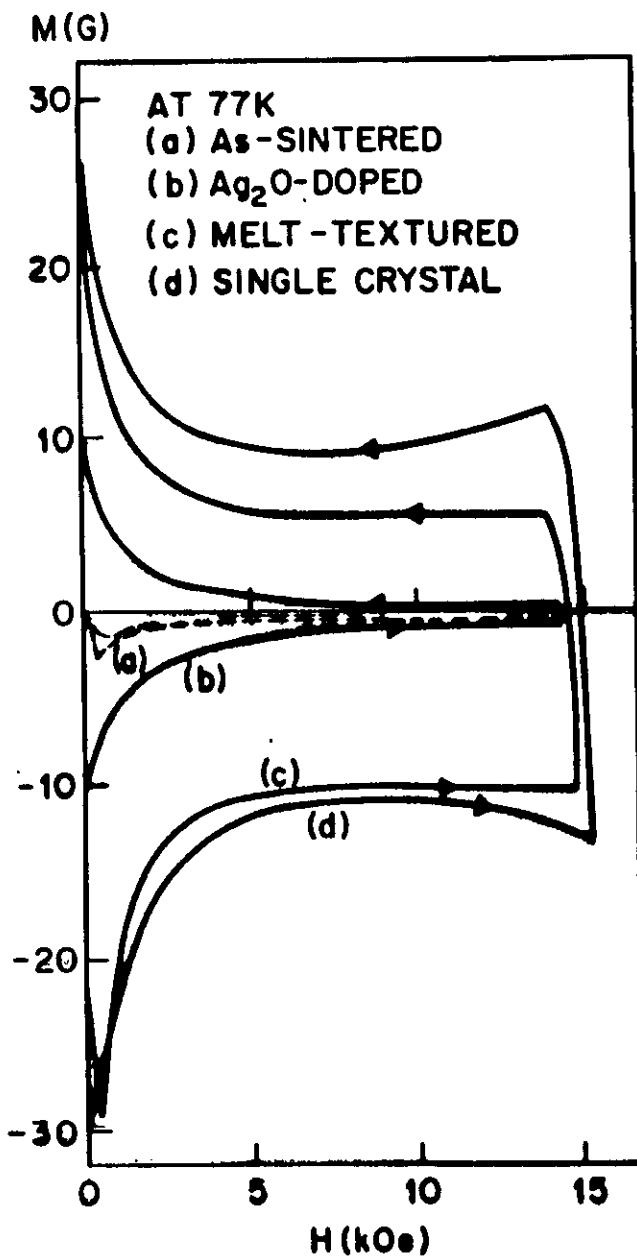
$$\Delta M = \frac{J_c t}{30}$$

Campbell & Brattet
Critical Currents in Superconductors
(Taylor & Francis, London)

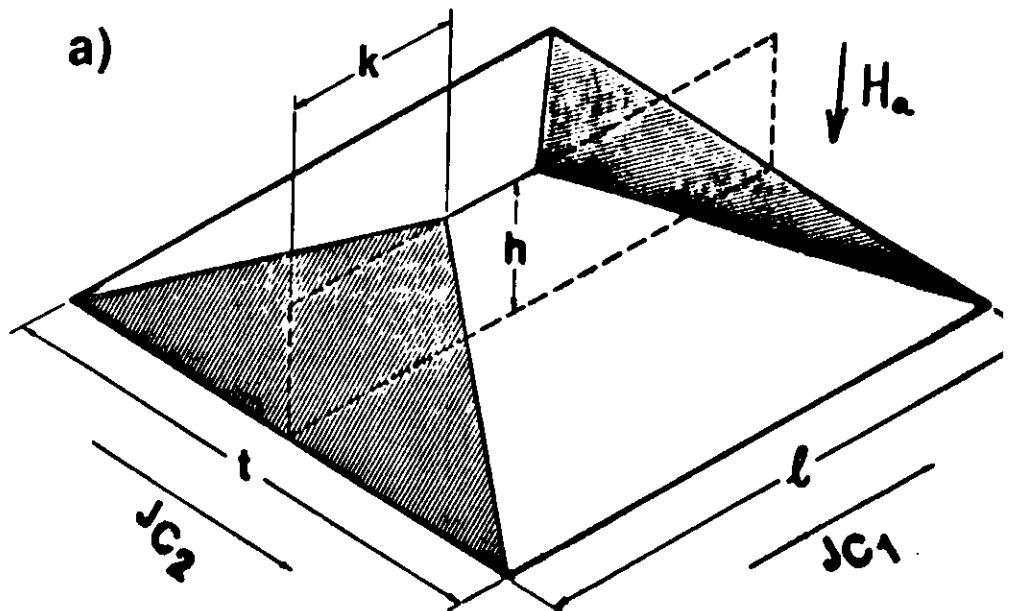


van Dover et al. PRB 27(1983)
1919

if J_c anisotropic, must use appropriate angle of repose for each direction



$$\Delta M = \frac{J_{c1} t}{20} \left(1 - \frac{\pi}{32} \frac{J_{c1}}{J_{c2}} \right)$$



$\text{Ba}_2\text{YCu}_3\text{O}_7$:
result 30 K

$$J_c^{ab} = 7.1 \cdot 10^5 \text{ A/cm}^2$$

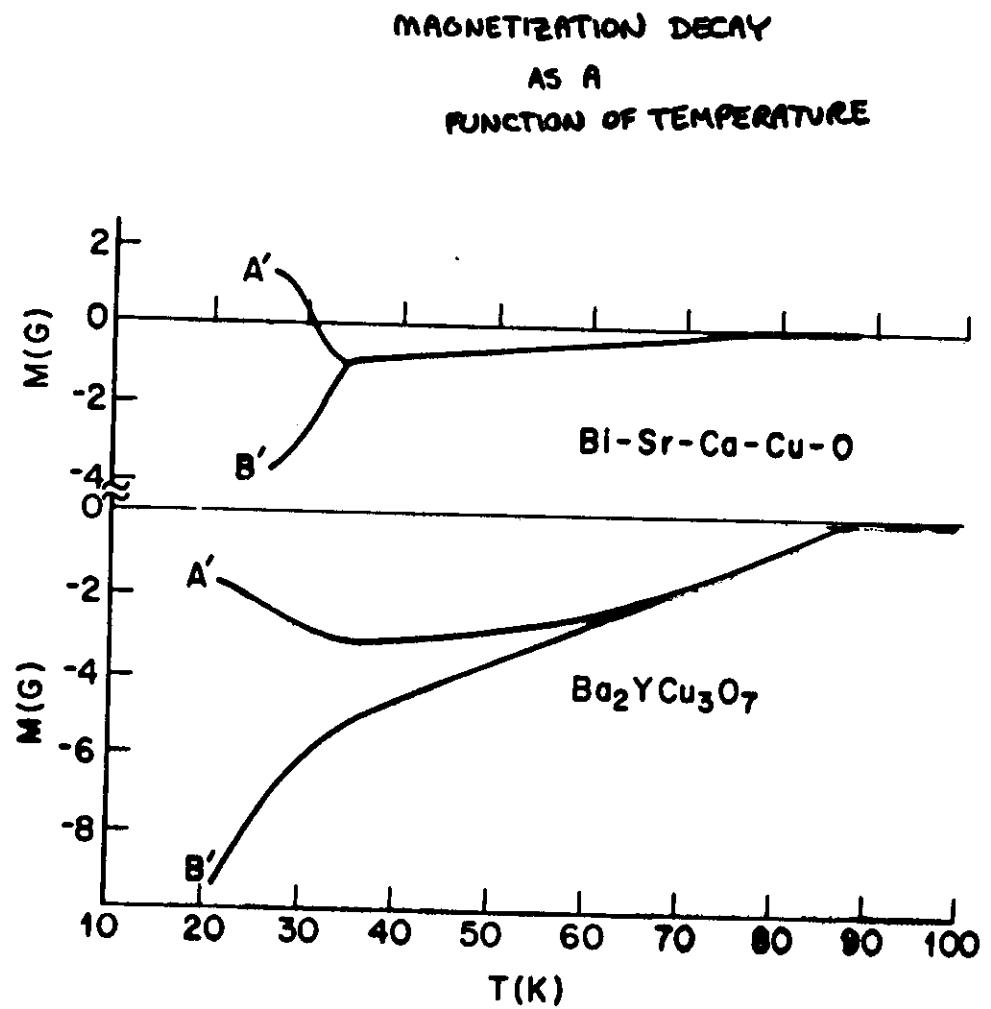
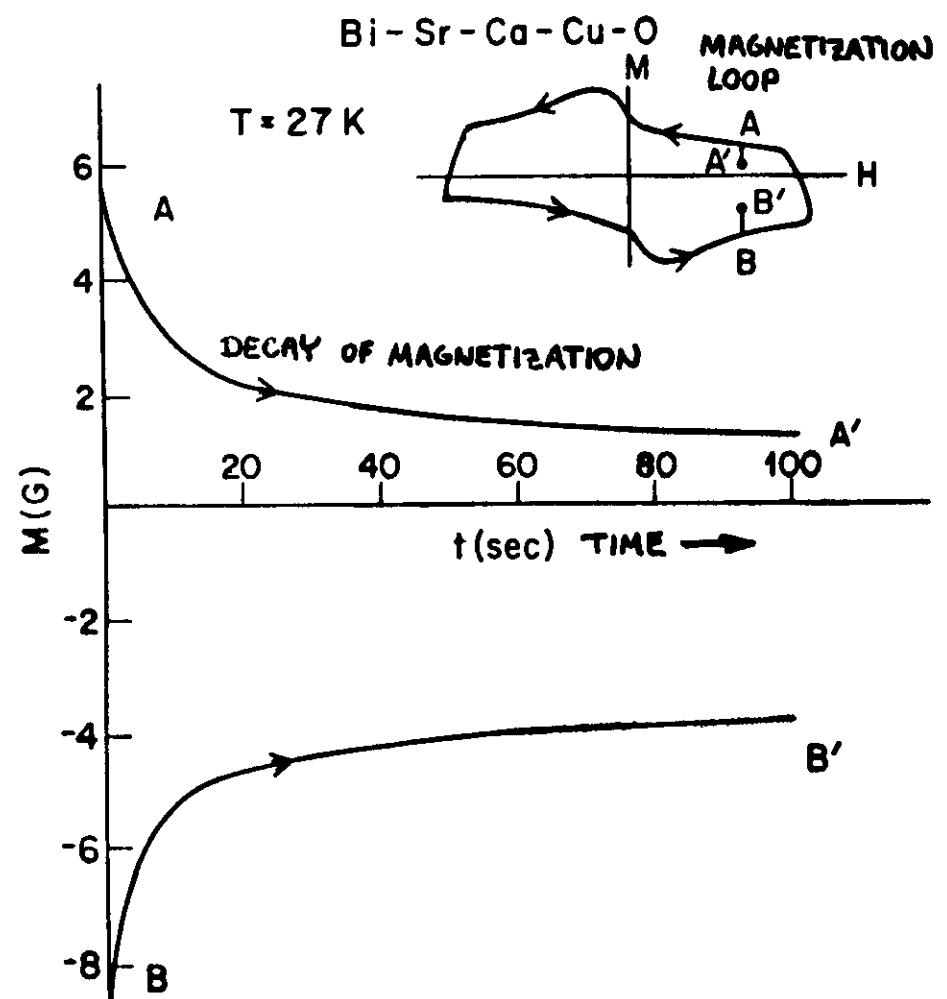
$$J_c^{abc} = 4.9 \cdot 10^6$$

flux motion \parallel to twins

$$J_c' = 2.2 \cdot 10^4$$

Gyorgy et al. APL (preprint)

twins not important at 30K!



Gyongy et al. ARS 52 (1978)

OUTSTANDING PROBLEMS

TRANSPORT + MAGNETICS

a. how do you vet ceramics + crystals
case-by-case

i. normal-state transport superconductivity they must relate
to n/s properties

$\rho(T)$ perhaps perturb by doping
 $R_s(T)$ but how to interpret?
other magnetotronics, thermotronics, thermomagnetics...

ii. N-T phase diagram framework: PLATE CREEP
what is V_c (flux bundle size, $\langle \Phi_b \rangle$)
melted phases? entanglement? glassy phases? hysteresis?
→ neutron scattering

iii. nature of pinning sites
relationship between F_p , U_0
different pinning mechanism at different T
intrinsic pinning?
engineering pin site density

iv. dissipation
possible insight into dynamics
understand high dissipation regime?